

CCG15-48-S**

EVALUATION DATA

型式データ

INDEX

	PAGE
1. 測定方法 Evaluation Method	
1-1. 測定回路 Measurement Circuits	3
(1) 静特性、待機電力特性、通電ドリフト特性、その他特性 Steady state, Standby power, Warm up voltage drift and Other characteristics	
(2) 入力サージ電流(突入電流)波形 Inrush current waveform	
(3) 出力リップル、ノイズ波形 Output ripple and noise waveform	
(4) EMI特性 Electro-Magnetic Interference characteristics	
1-2. 使用測定機器 List of equipment used	5
2. 特性データ Characteristics	
2-1. 静特性 Steady state characteristics	
(1) 入力・負荷・温度変動 Regulation - line and load, Temperature drift	6
(2) 出力電圧・出力リップル・ノイズ電圧 対 入力電圧 Output voltage and Output ripple and noise voltage vs. Input voltage	7
(3) 入力電流・効率 対 出力電流 Input current and Efficiency vs. Output current	9
(4) 効率 対 入力電圧 Efficiency vs. Input voltage	11
(5) 起動・遮断電圧特性 Start up and Drop out voltage characteristics	13
2-2. 待機電力特性 Standby power characteristics	15
2-3. 通電ドリフト特性 Warm up voltage drift characteristics	17
2-4. 過電流保護特性 Over current protection (OCP) characteristics	19
2-5. 出力立ち上がり・立ち下がり特性 Output rise and fall characteristics	21
2-6. 過渡応答(負荷急変)特性 Dynamic load response characteristics	29
2-7. 入力サージ電流(突入電流)特性 Inrush current characteristics	30
2-8. 出力リップル、ノイズ波形 Output ripple and noise waveform	31
2-9. EMI特性 Electro-Magnetic Interference characteristics	32

使用記号 Terminology used

	定義 Definition
Vin 入力電圧 Input voltage
Vo 出力電圧 Output voltage
Vrc RC電圧 RC voltage
Iin 入力電流 Input current
Io 出力電流 Output current
Ta 周囲温度 Ambient temperature
f 周波数 Frequency

※ 当社測定条件における結果であり、参考値としてお考え願います。

Test results are reference data based on our measurement condition.

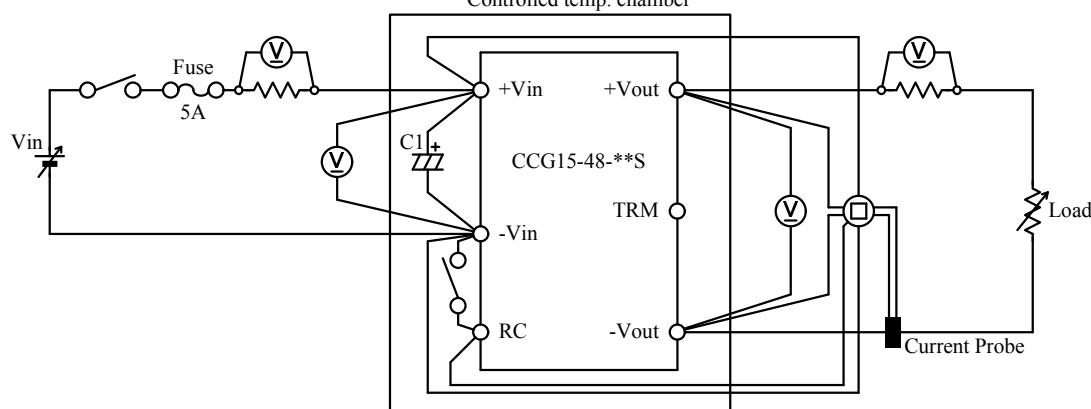
1. 測定方法 Evaluation Method

1-1. 測定回路 Measurement Circuits

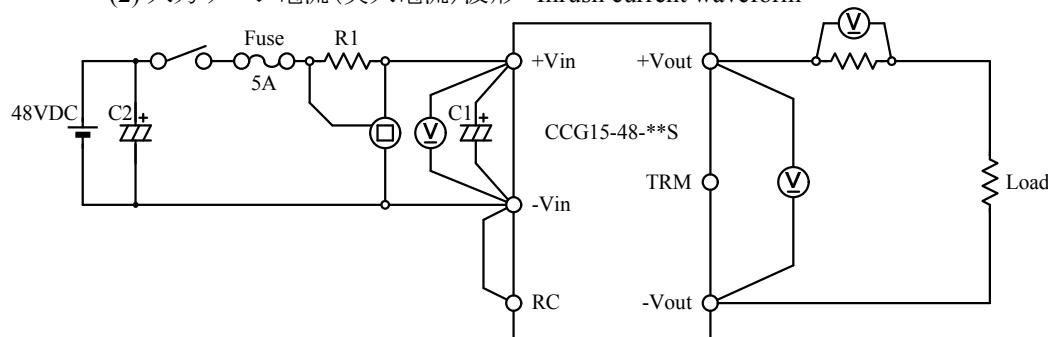
(1) 静特性、待機電力特性、通電ドリフト特性、その他特性

Steady state, Standby power, Warm up voltage drift and Other characteristics

Controlled temp. chamber

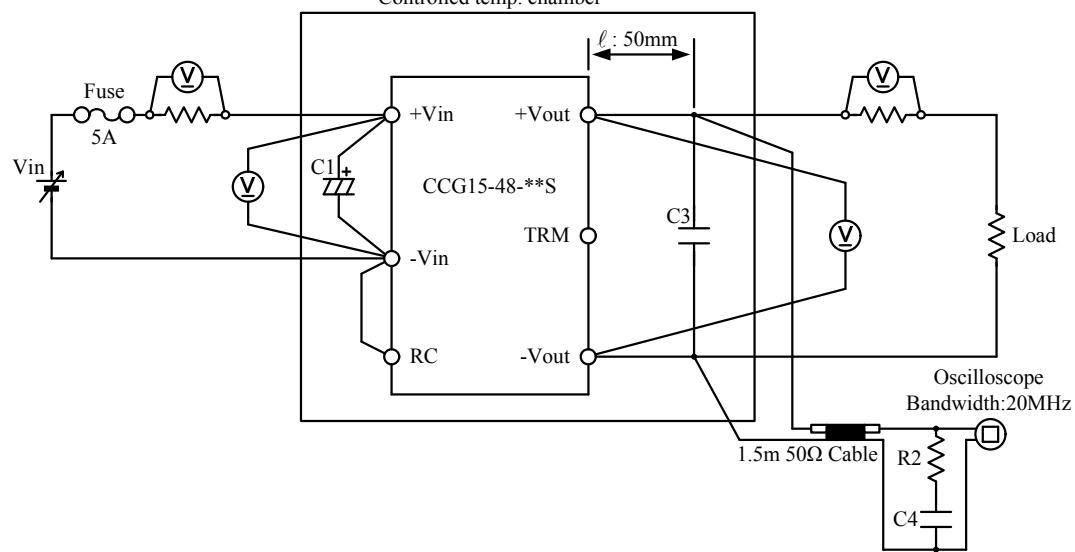


(2) 入力サージ電流(突入電流)波形 Inrush current waveform



(3) 出力リップル、ノイズ電圧、波形 Output ripple and noise voltage and waveform

Controlled temp. chamber



C1 : 47μF

Electrolytic Capacitor

C2 : 8000μF

Electrolytic Capacitor

C3 : 22μF

Ceramic Capacitor

C4 : 4700pF

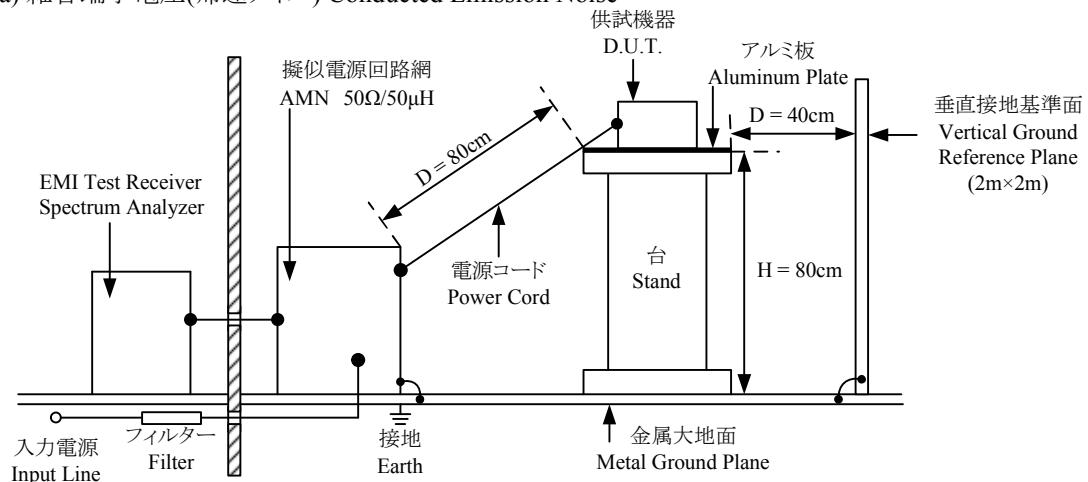
Ceramic Capacitor

R1 : 0.01Ω

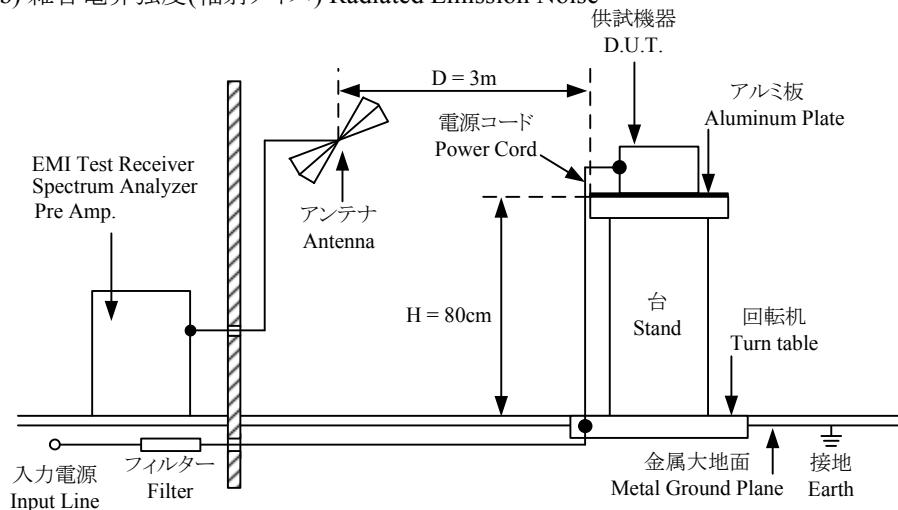
R2 : 50Ω

(4) EMI特性 Electro-Magnetic Interference characteristics

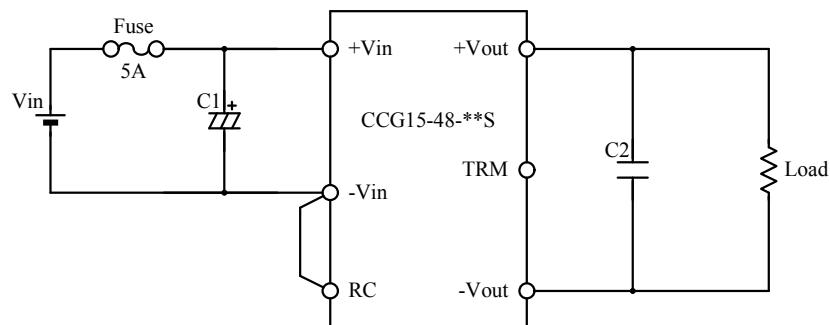
(a) 雑音端子電圧(帰還ノイズ) Conducted Emission Noise



(b) 雑音電界強度(輻射ノイズ) Radiated Emission Noise



VCCI class A 対応アプリケーション VCCI class A application system

C1 : 82μF
C2 : 22μFElectrolytic Capacitor
Ceramic Capacitor

1-2. 使用測定機器 List of equipment used

	EQUIPMENT USED	MANUFACTURER	MODEL NO.
1	DIGITAL STORAGE OSCILLOSCOPE	YOKOGAWA ELECT.	DL1740 / DL1740E
2	DIGITAL MULTIMETER	AGILENT	34970A
3	CURRENT PROBE	YOKOGAWA ELECT.	701932
4	CURRENT PROBE	AGILENT	N2774A
5	SHUNT RESISTER	YOKOGAWA ELECT.	2215
6	DYNAMIC DUMMY LOAD	TAKASAGO	FK-200L / FK-600L
7	CVCF	TAKASAGO	AA2000XG
8	CVCF	NF	ES1000S / ES10000S
9	DC POWER SUPPLY	TDK-Lambda	Z+100-8
10	CONTROLLED TEMP. CHAMBER	ESPEC	SU-261 / SU-641
11	EMI TEST RECEIVER / SPECTRUM ANALYZER	ROHDE & SCHWARZ	ESCI
12	PRE AMP.	SONOMA	310N
13	AMN	KIKUSUI	KNW-242C
14	ANTENNA	SCHWARZBECK	BBA9106/VHA9103
15	ANTENNA	SCHWARZBECK	UHALP9107

2. 特性データ Characteristics

2-1. 静特性 Steady state characteristics

(1) 入力・負荷・温度変動 Regulation - line and load, Temperature drift

3.3V	1. Regulation - line and load	Condition	Ta : 25 °C
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Io \ Vin	18VDC	24VDC	48VDC	76VDC	Line regulation	
0%	3.301V	3.301V	3.301V	3.300V	1mV	0.030%
50%	3.300V	3.300V	3.300V	3.300V	0mV	0.000%
100%	3.299V	3.299V	3.299V	3.298V	1mV	0.030%
Load regulation	2mV	2mV	2mV	2mV		
	0.061%	0.061%	0.061%	0.061%		

2. Temperature drift	Conditions	Vin : 48 VDC
		Io : 100 %

Ta	-40°C	25°C	85°C	Temperature stability
Vo	3.278V	3.299V	3.302V	24mV
	0.727%			

5V	1. Regulation - line and load	Condition	Ta : 25 °C
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Io \ Vin	18VDC	24VDC	48VDC	76VDC	Line regulation	
0%	5.011V	5.011V	5.011V	5.009V	2mV	0.040%
50%	5.010V	5.010V	5.010V	5.009V	1mV	0.020%
100%	5.009V	5.009V	5.009V	5.008V	1mV	0.020%
Load regulation	2mV	2mV	2mV	1mV		
	0.040%	0.040%	0.040%	0.020%		

2. Temperature drift	Conditions	Vin : 48 VDC
		Io : 100 %

Ta	-40°C	25°C	85°C	Temperature stability
Vo	4.976V	5.009V	5.016V	40mV
	0.800%			

12V	1. Regulation - line and load	Condition	Ta : 25 °C
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Io \ Vin	18VDC	24VDC	48VDC	76VDC	Line regulation	
0%	12.054V	12.055V	12.054V	12.054V	1mV	0.008%
50%	12.053V	12.053V	12.053V	12.053V	0mV	0.000%
100%	12.052V	12.053V	12.052V	12.053V	1mV	0.008%
Load regulation	2mV	2mV	2mV	1mV		
	0.017%	0.017%	0.017%	0.008%		

2. Temperature drift	Conditions	Vin : 48 VDC
		Io : 100 %

Ta	-40°C	25°C	85°C	Temperature stability
Vo	12.062V	12.052V	12.058V	10mV
	0.083%			

15V	1. Regulation - line and load	Condition	Ta : 25 °C
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Io \ Vin	18VDC	24VDC	48VDC	76VDC	Line regulation	
0%	15.121V	15.122V	15.121V	15.120V	2mV	0.013%
50%	15.120V	15.120V	15.119V	15.120V	1mV	0.007%
100%	15.120V	15.120V	15.119V	15.119V	1mV	0.007%
Load regulation	1mV	2mV	2mV	1mV		
	0.007%	0.013%	0.013%	0.007%		

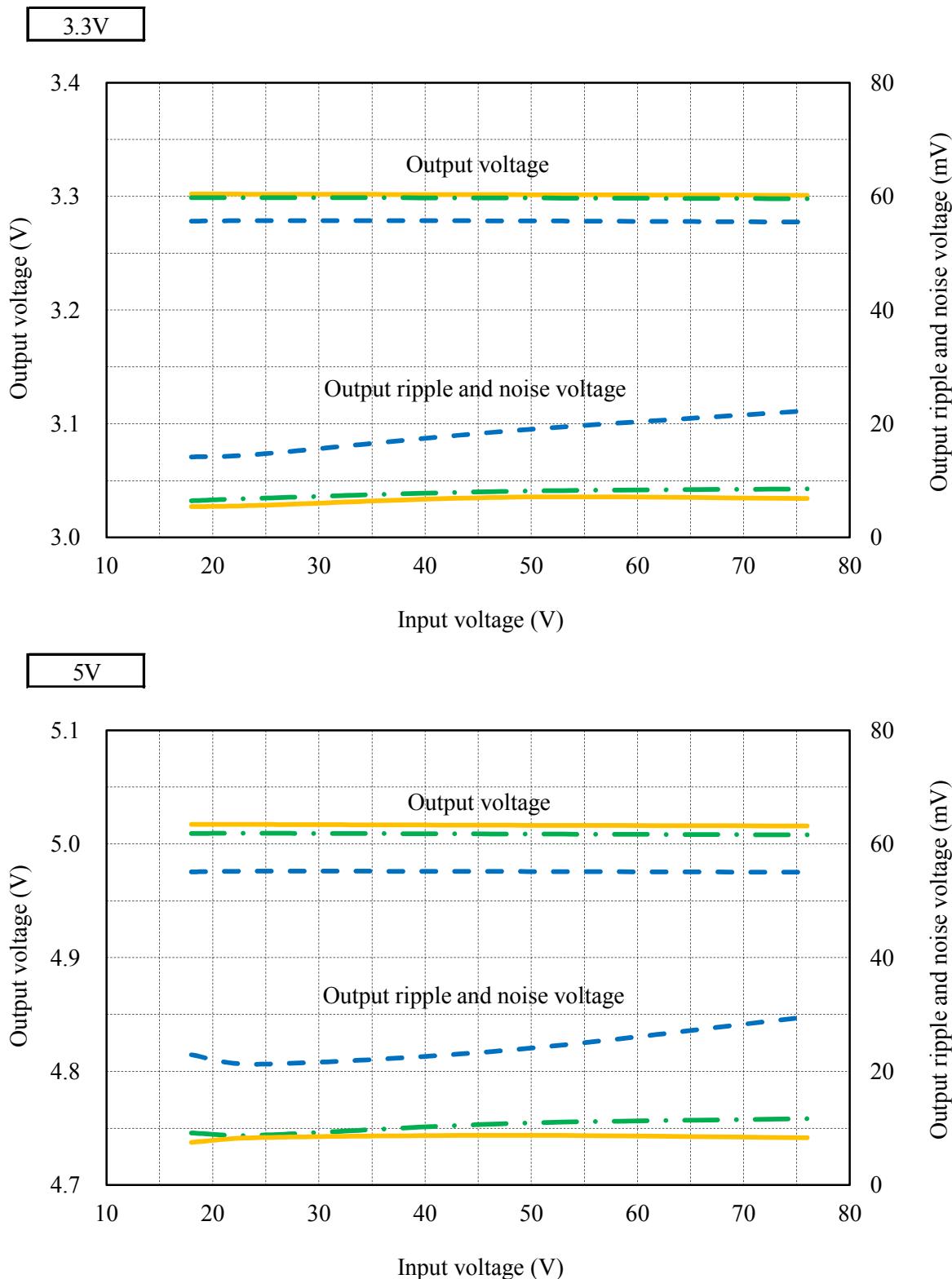
2. Temperature drift	Conditions	Vin : 48 VDC
		Io : 100 %

Ta	-40°C	25°C	85°C	Temperature stability
Vo	15.115V	15.119V	15.118V	4mV
	0.027%			

(2) 出力電圧・出力リップルノイズ電圧 対 入力電圧

Output voltage and Output ripple and noise voltage vs. Input voltage

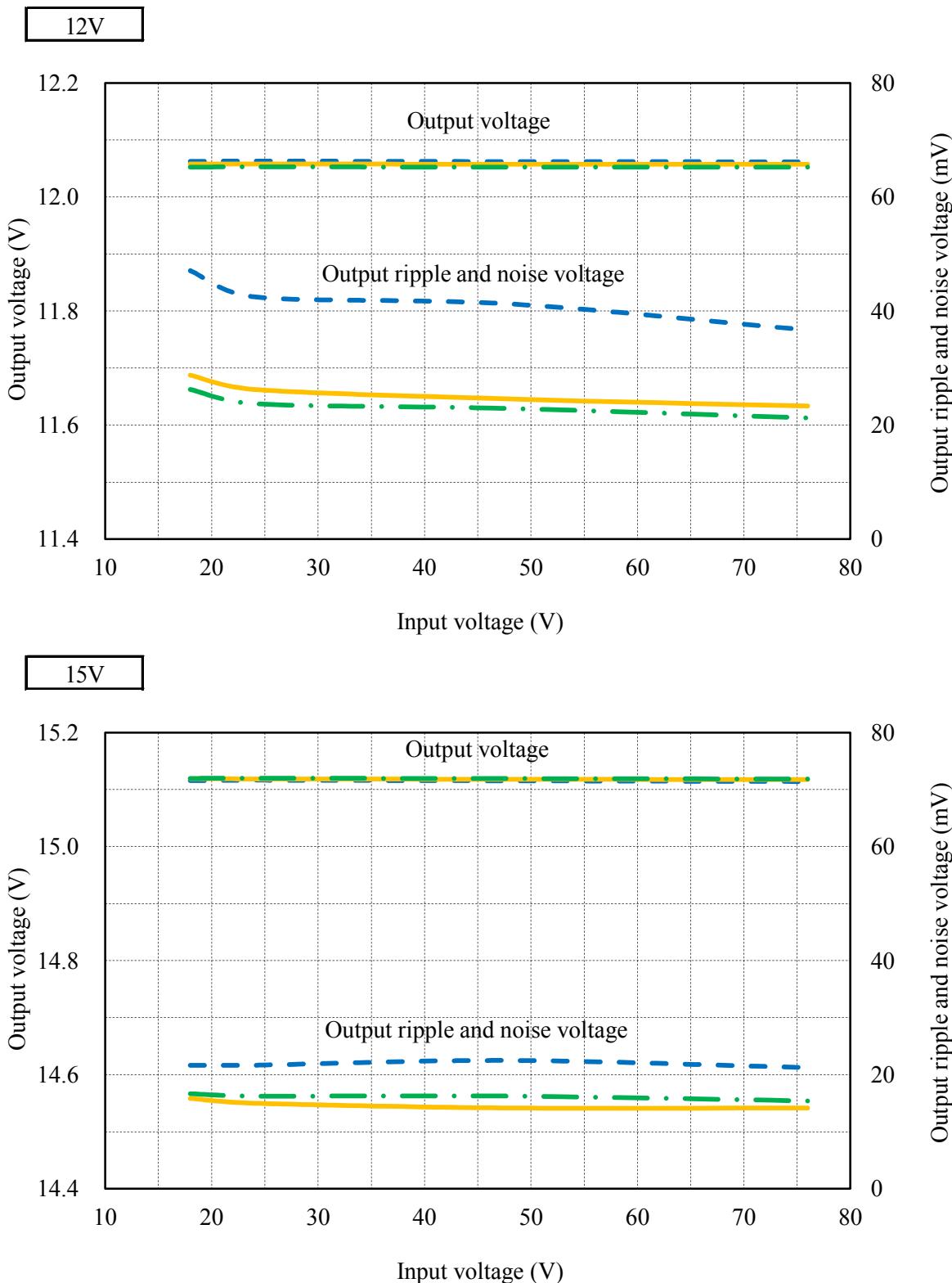
Conditions Io : 100 %
 Ta : -40 °C -----
 : 25 °C - - -
 : 85 °C - - - -



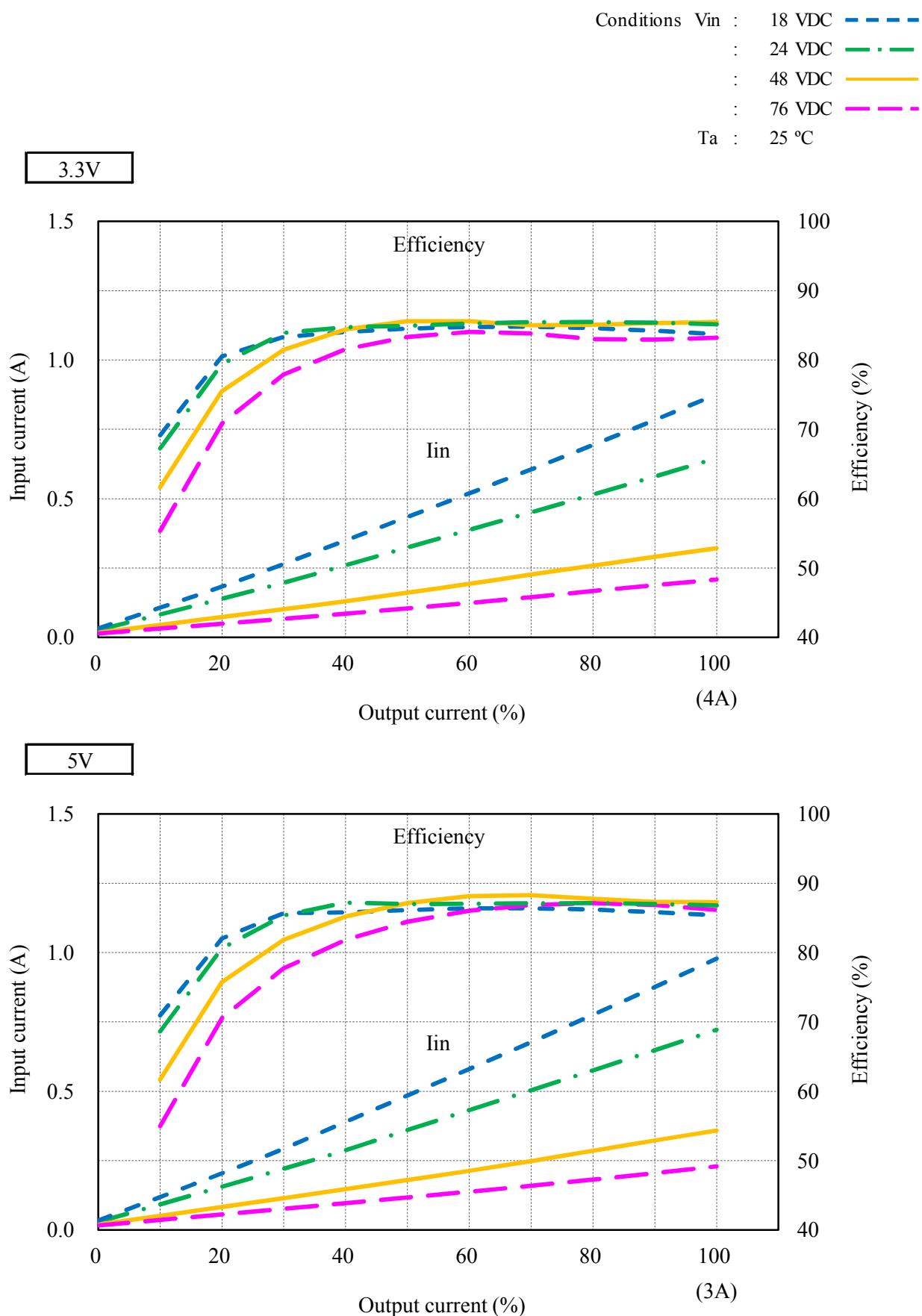
(2) 出力電圧・出力リップルノイズ電圧 対 入力電圧

Output voltage and Output ripple and noise voltage vs. Input voltage

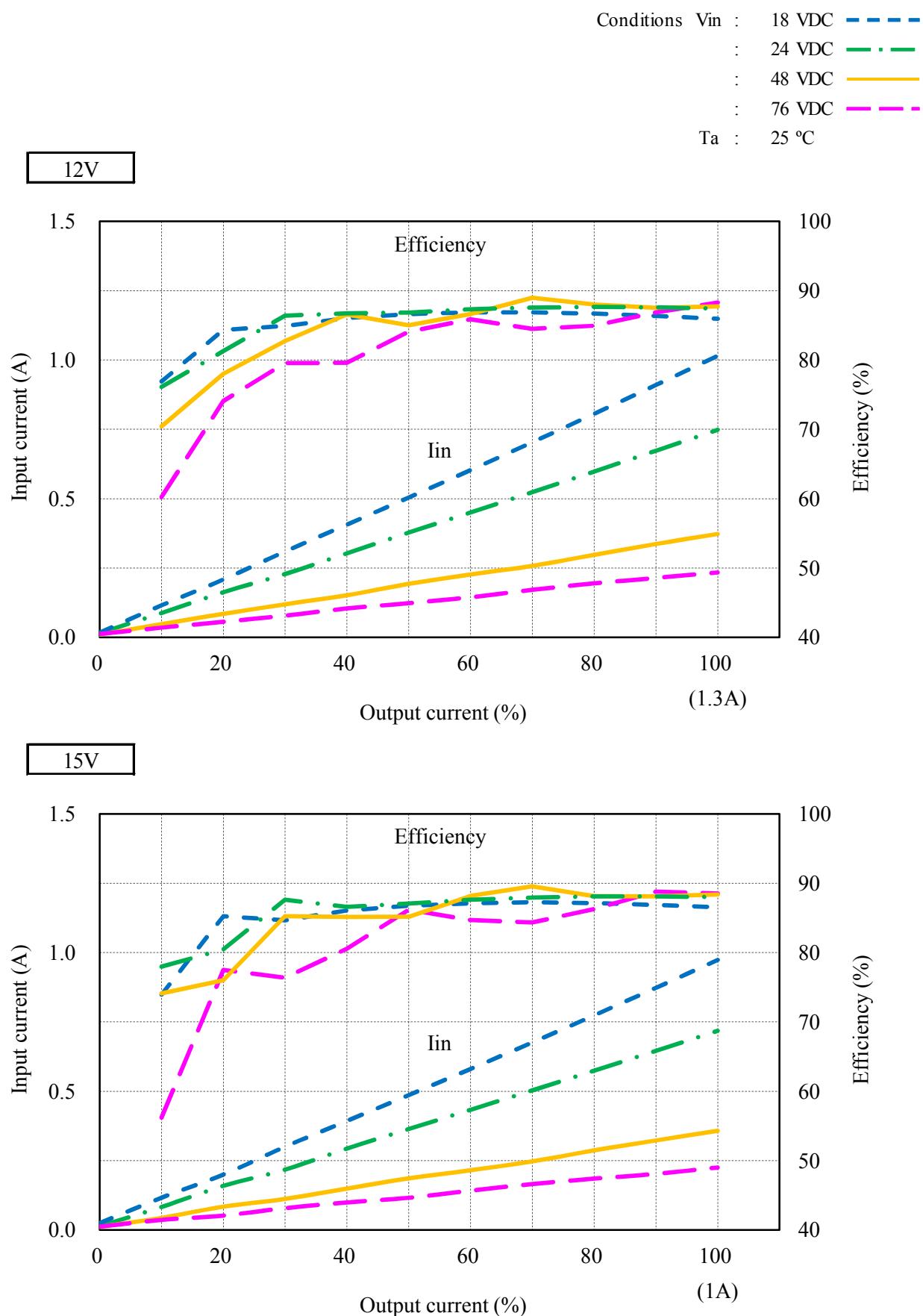
Conditions Io : 100 %
 Ta : -40 °C ---
 : 25 °C -·-
 : 85 °C —



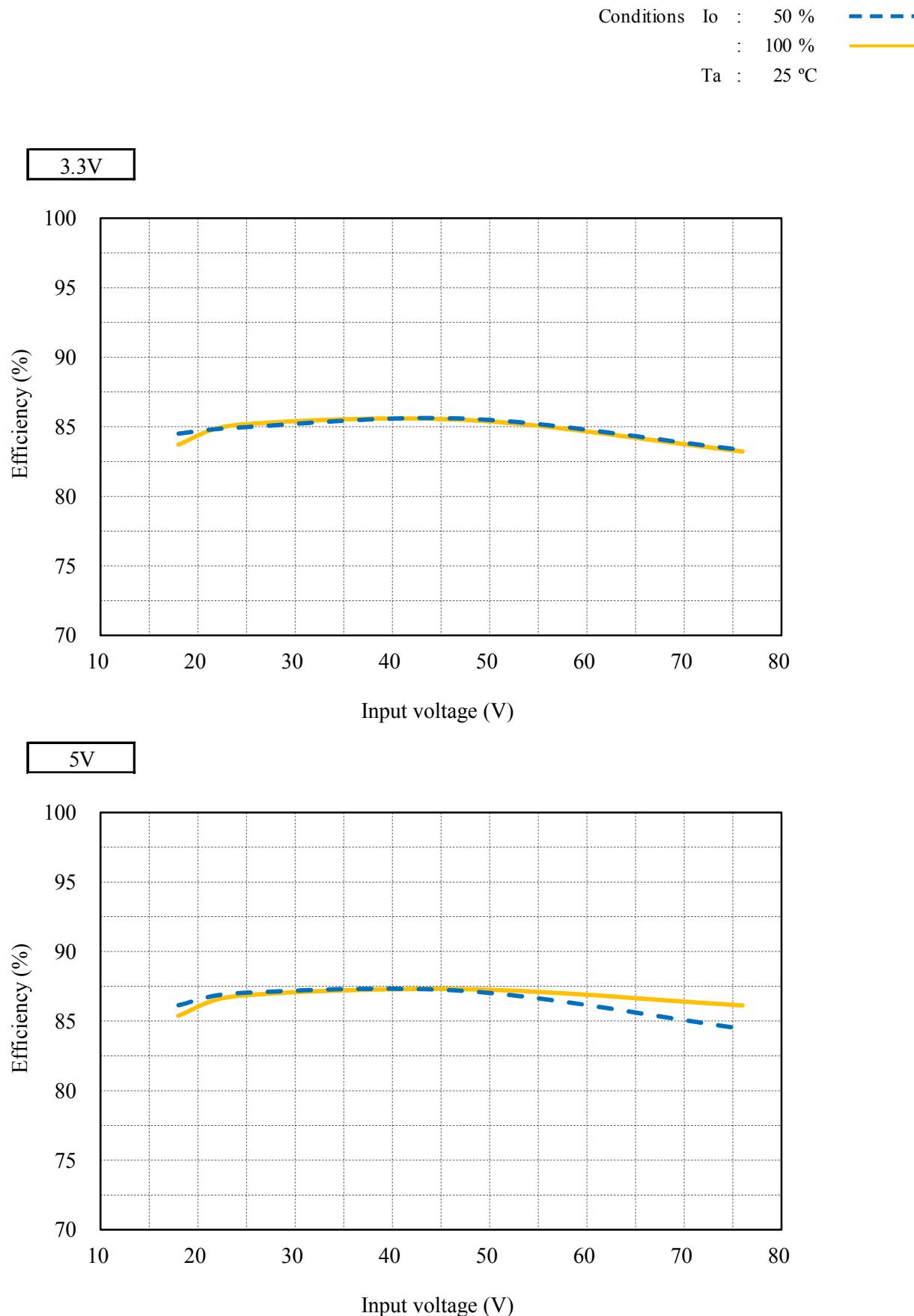
(3) 入力電流・効率 対 出力電流 Input current and Efficiency vs. Output current



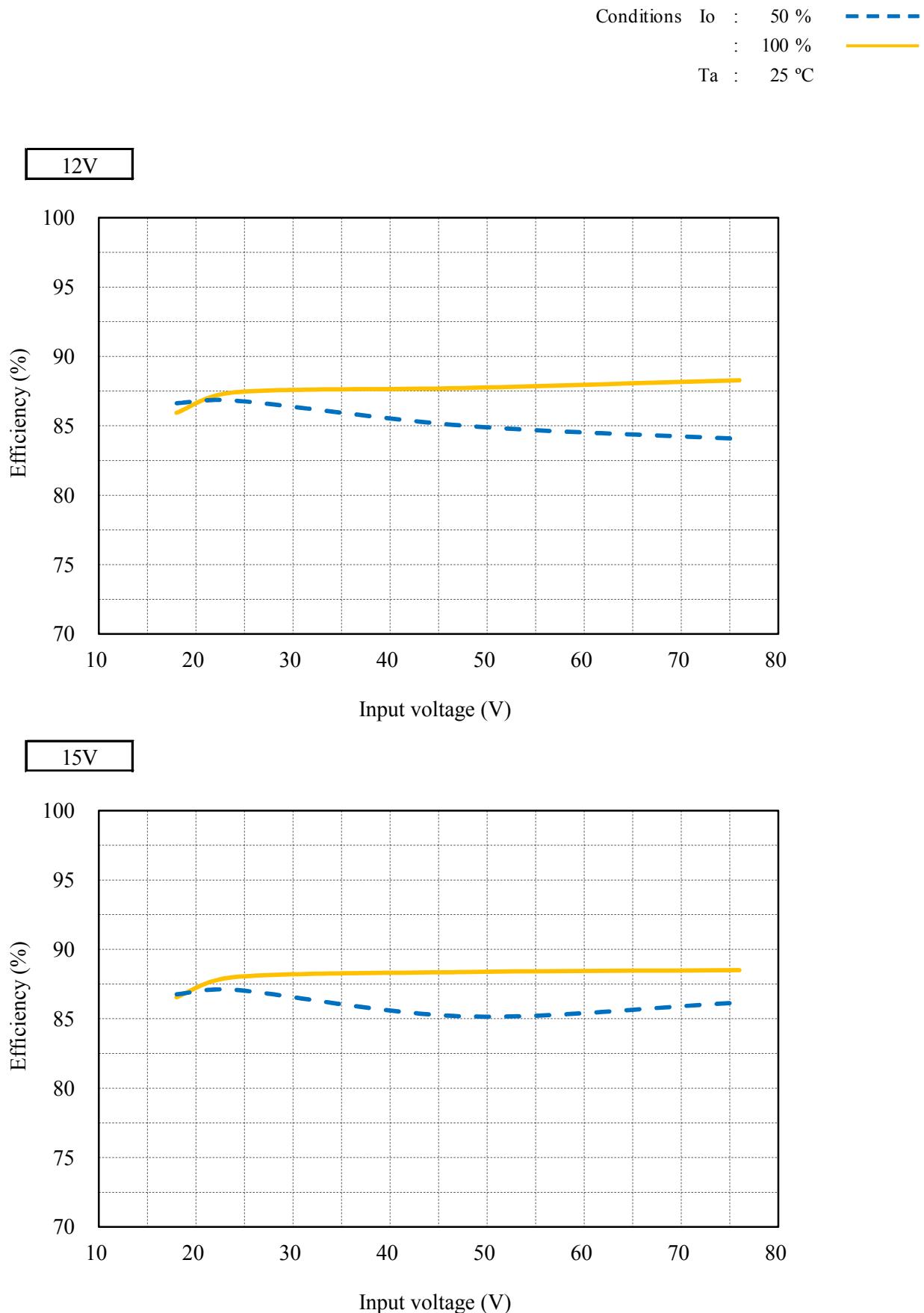
(3) 入力電流・効率 対 出力電流 Input current and Efficiency vs. Output current



(4) 効率 対 入力電圧 Efficiency vs. Input voltage



(4) 効率 対 入力電圧 Efficiency vs. Input voltage



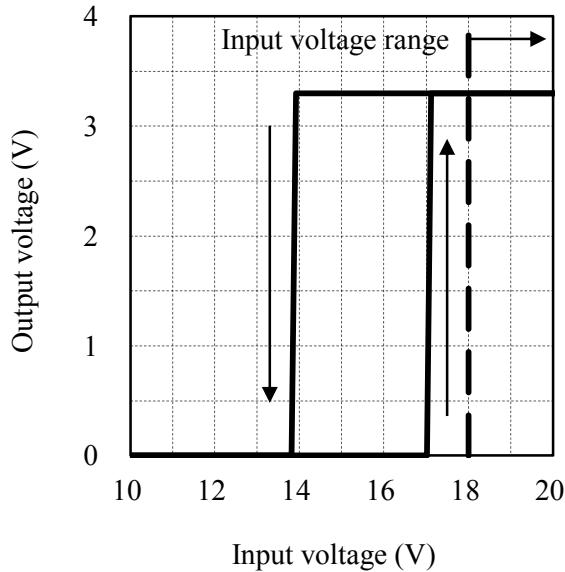
(5) 起動・遮断電圧特性 Start up and Drop out voltage characteristics

出力電圧 対 入力電圧

Output voltage vs. Input voltage

Conditions Io : 100 %
Ta : 25 °C

3.3V

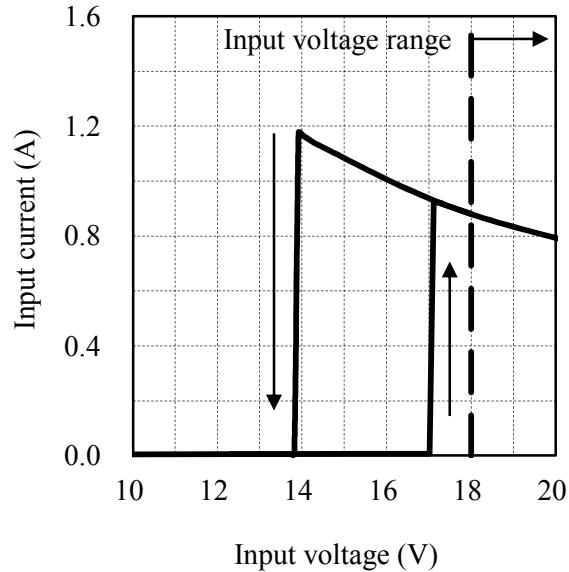


入力電流 対 入力電圧

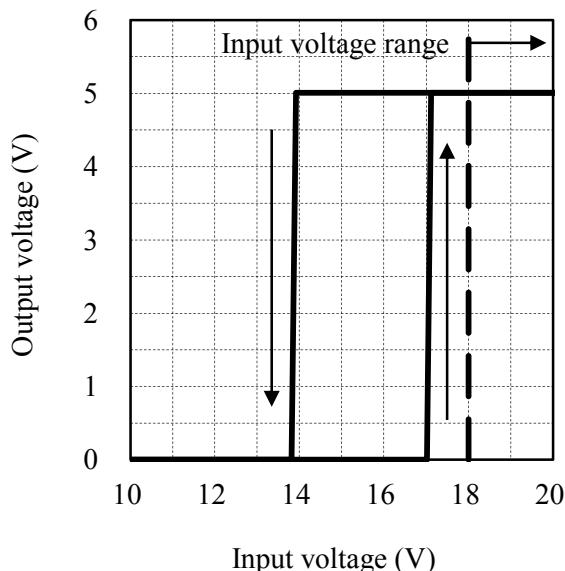
Input current vs. Input voltage

Conditions Io : 100 %
Ta : 25 °C

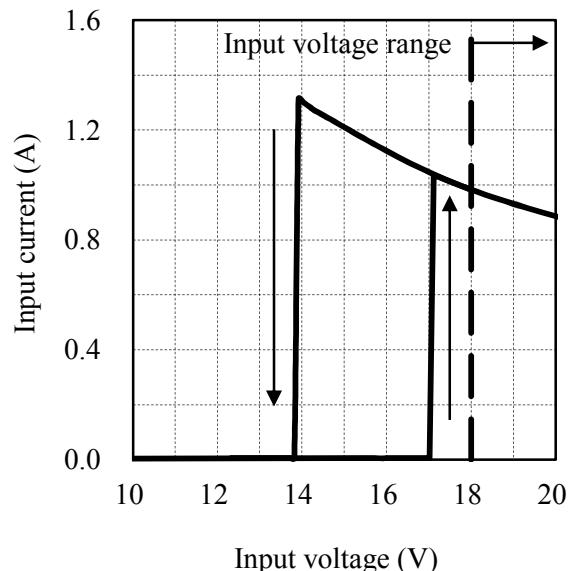
3.3V



5V



5V



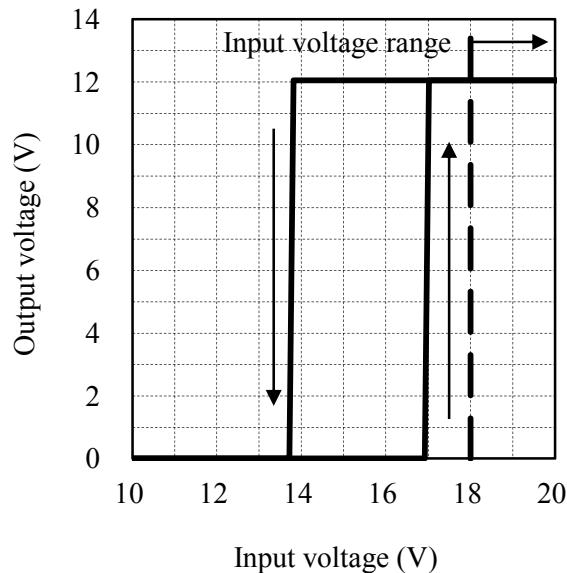
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出力電圧 対 入力電圧

Output voltage vs. Input voltage

Conditions Io : 100 %
Ta : 25 °C

12V

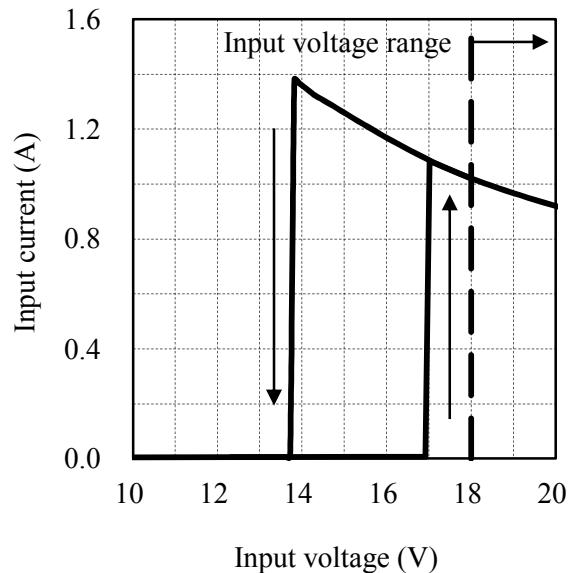


入力電流 対 入力電圧

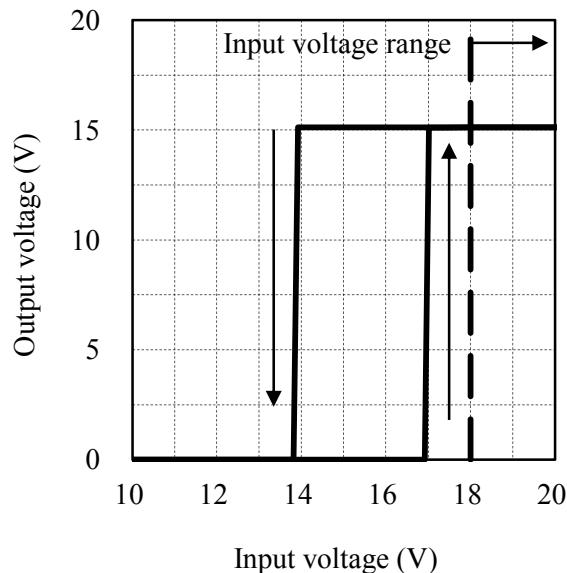
Input current vs. Input voltage

Conditions Io : 100 %
Ta : 25 °C

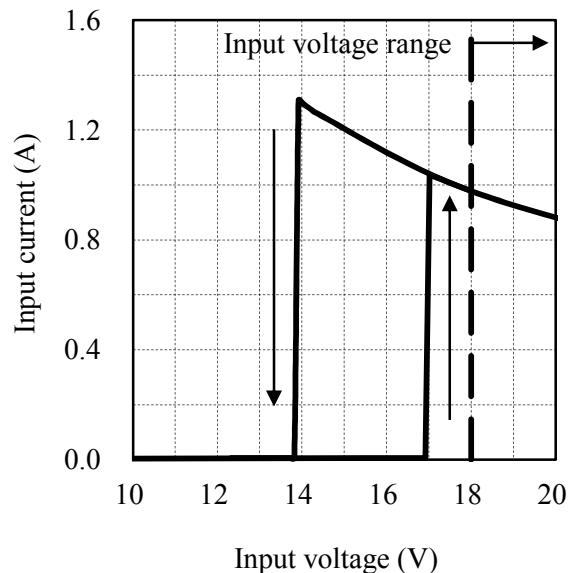
12V



15V



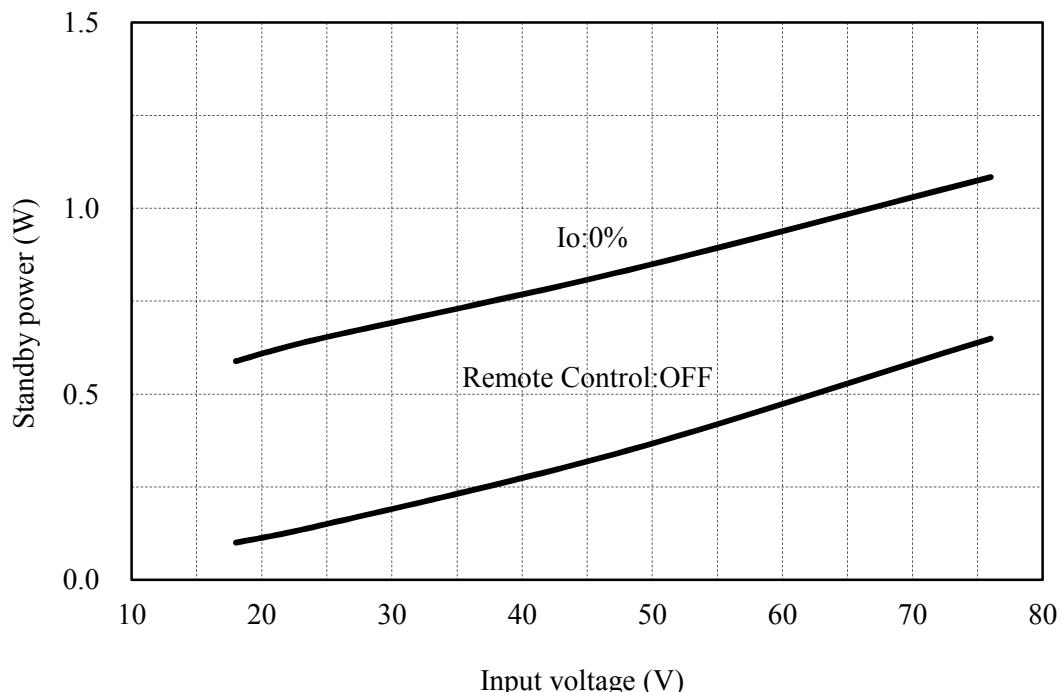
15V



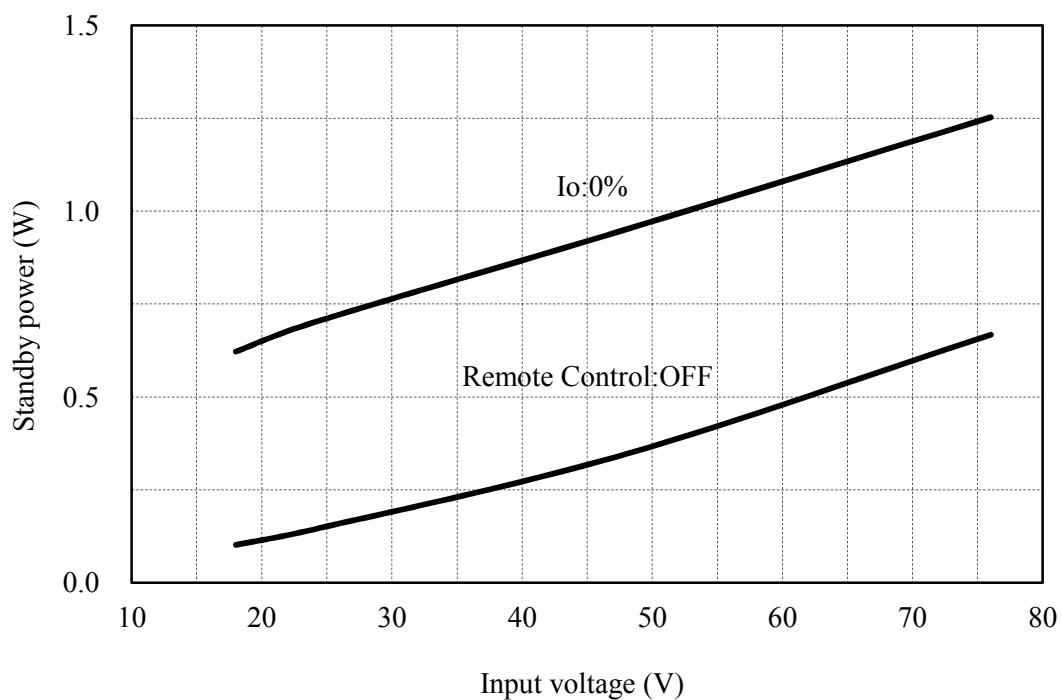
2-2. 待機電力特性 Standby power characteristics

Condition Ta : 25 °C

3.3V



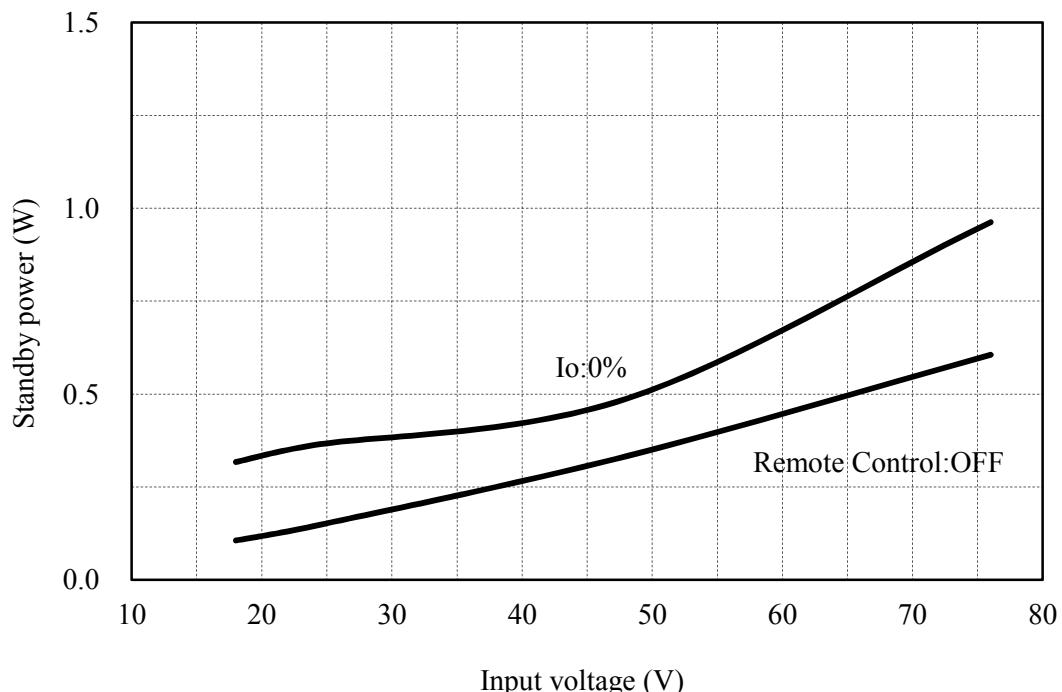
5V



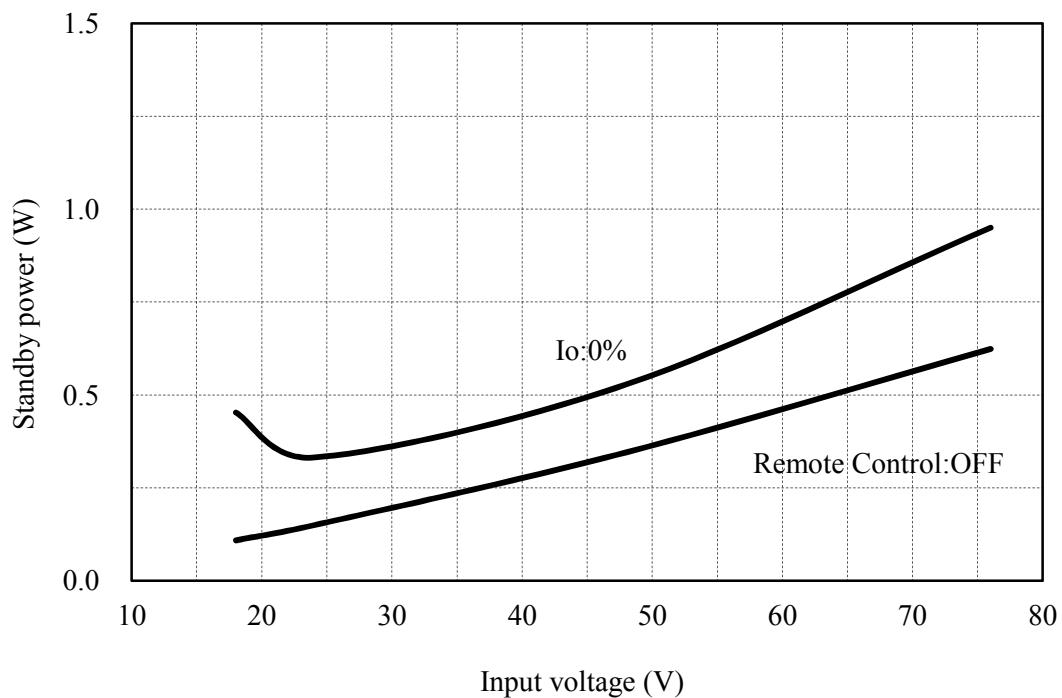
2-2. 待機電力特性 Standby power characteristics

Condition Ta : 25 °C

12V

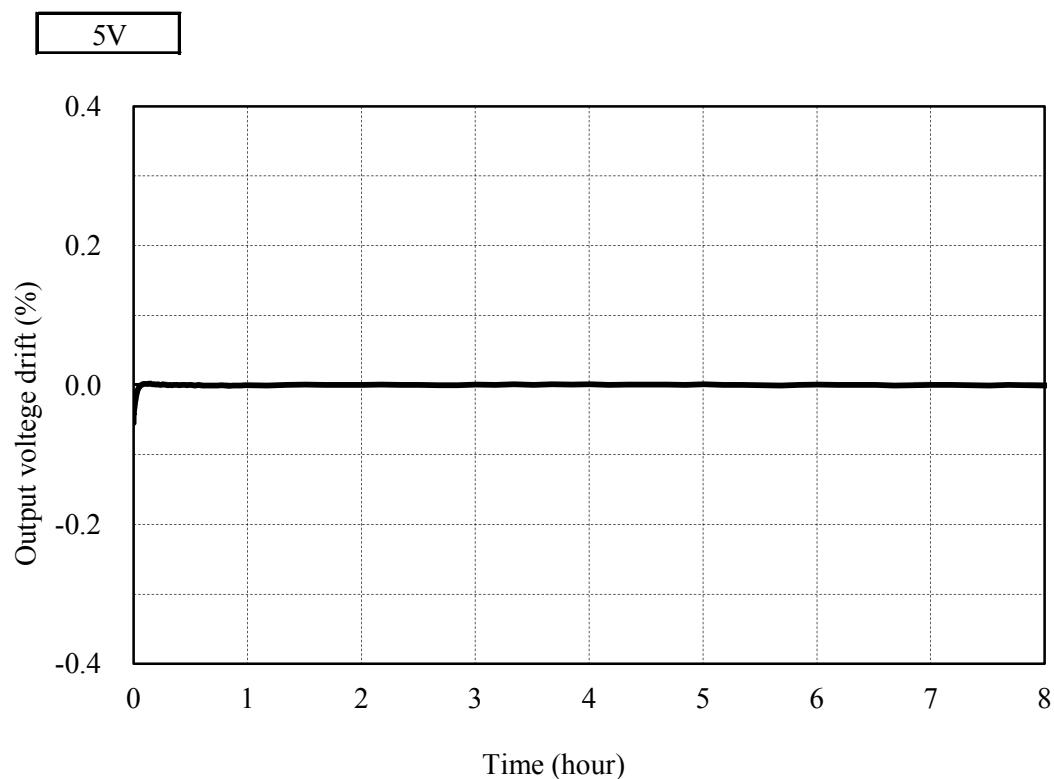
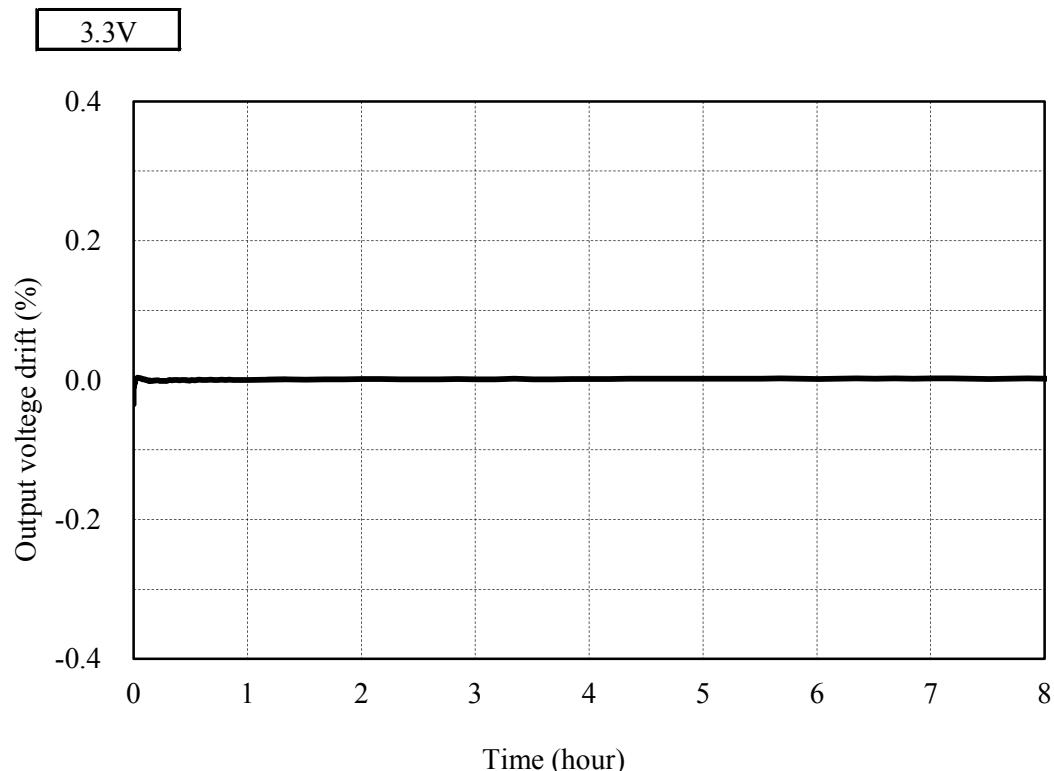


15V



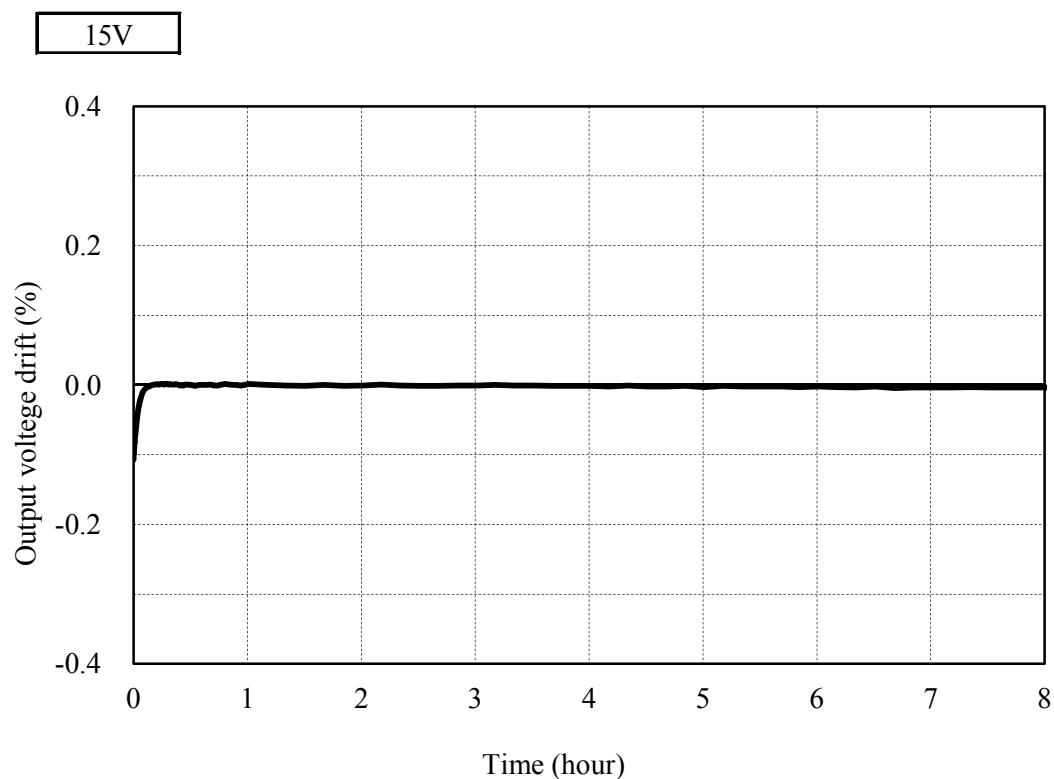
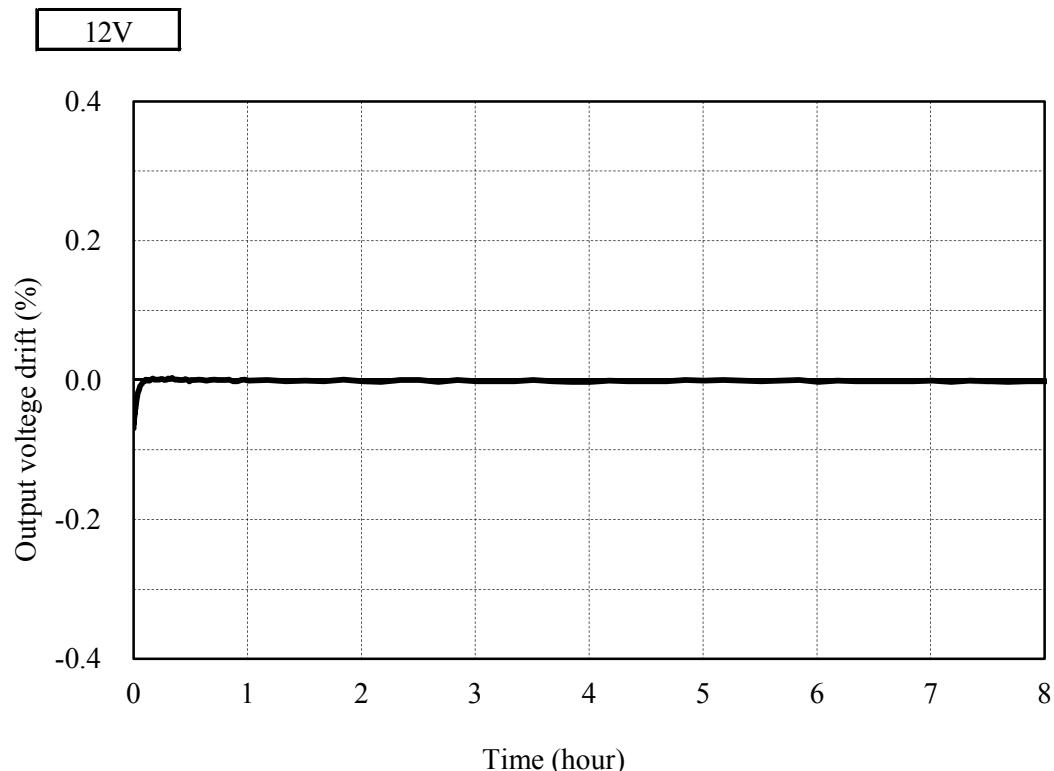
2-3. 通電ドリフト特性 Warm up voltage drift characteristics

Conditions Vin : 48 VDC
Io : 100 %
Ta : 25 °C



2-3. 通電ドリフト特性 Warm up voltage drift characteristics

Conditions Vin : 48 VDC
Io : 100 %
Ta : 25 °C



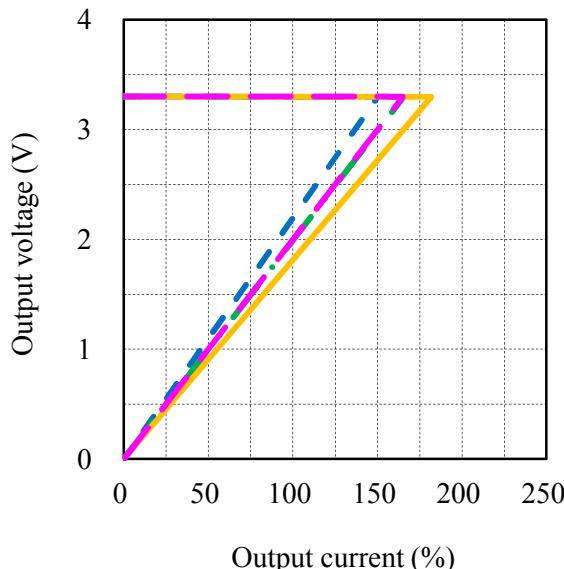
2-4. 過電流保護特性 Over current protection (OCP) characteristics

入力電圧依存性

Input voltage dependence

Conditions Vin : 18 VDC —
 : 24 VDC -·-
 : 48 VDC ---
 : 76 VDC —
 Ta : 25 °C

3.3V

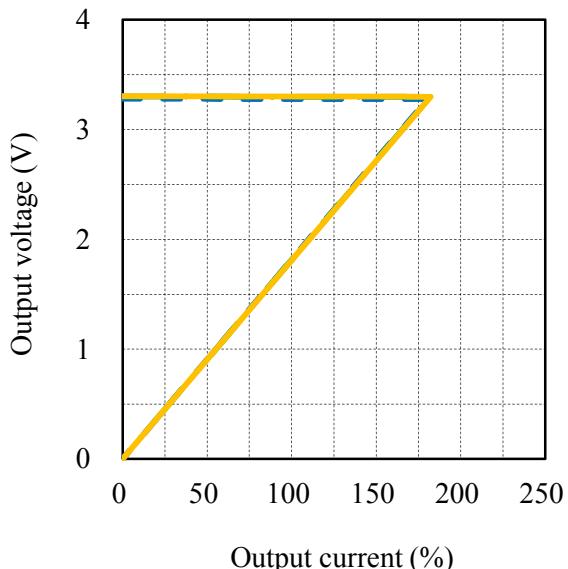


周囲温度依存性

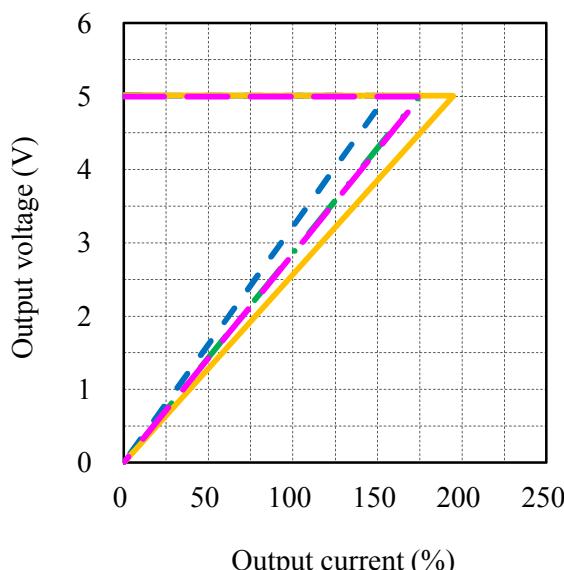
Ambient temperature dependence

Conditions Vin : 48 VDC
 Ta : -40 °C —
 25 °C -·-
 85 °C ---

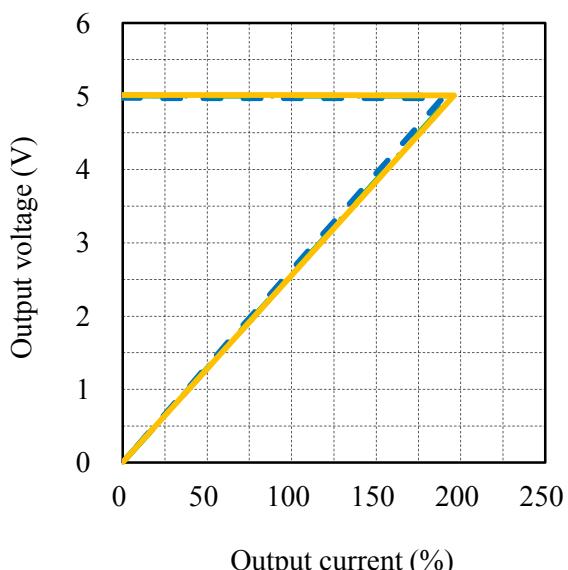
3.3V



5V



5V



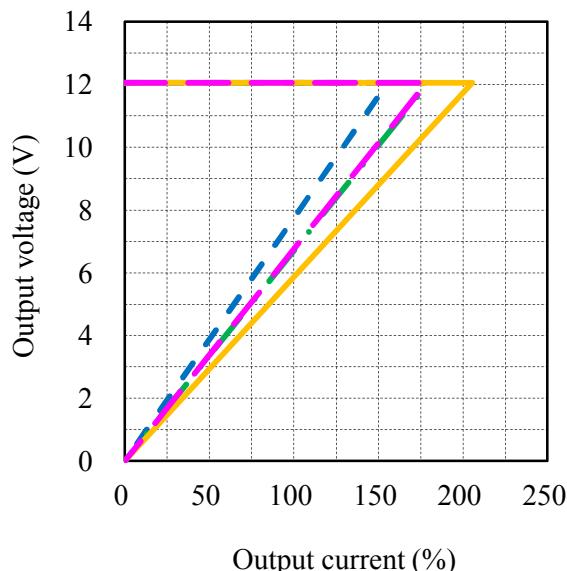
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Input voltage dependence

Conditions Vin : 18 VDC —
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12V

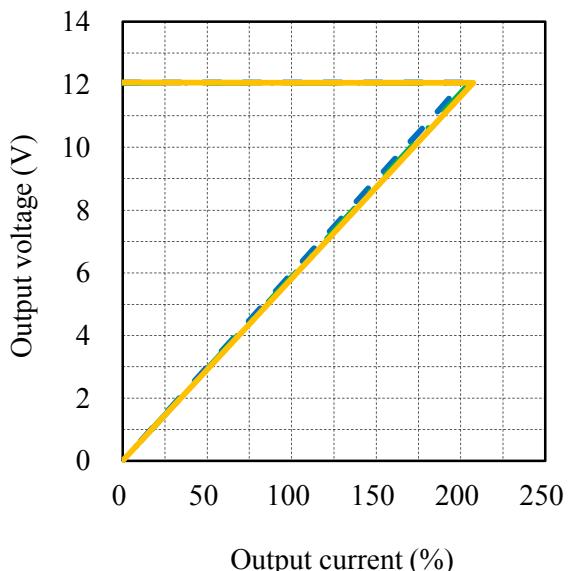


周囲温度依存性

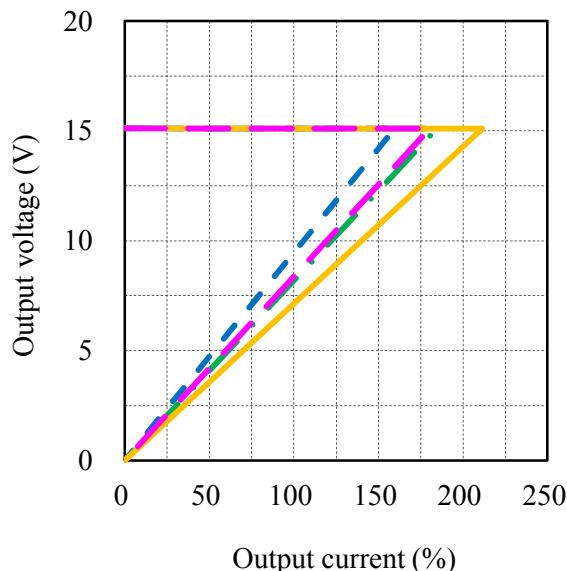
Ambient temperature dependence

Conditions Vin : 48 VDC
 Ta : -40 °C —
 25 °C -
 85 °C —

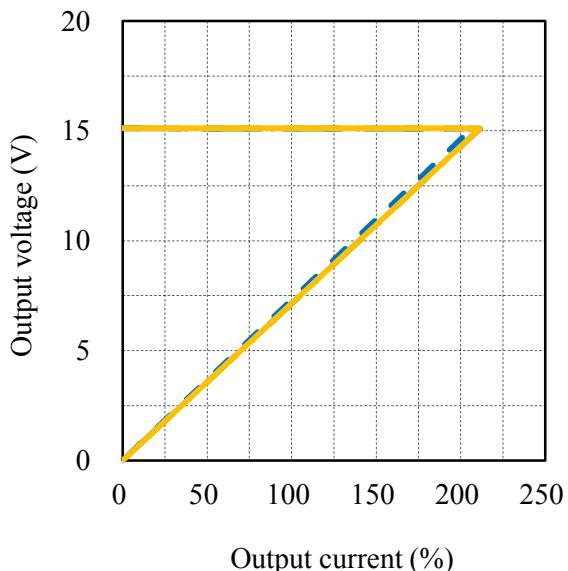
12V



15V

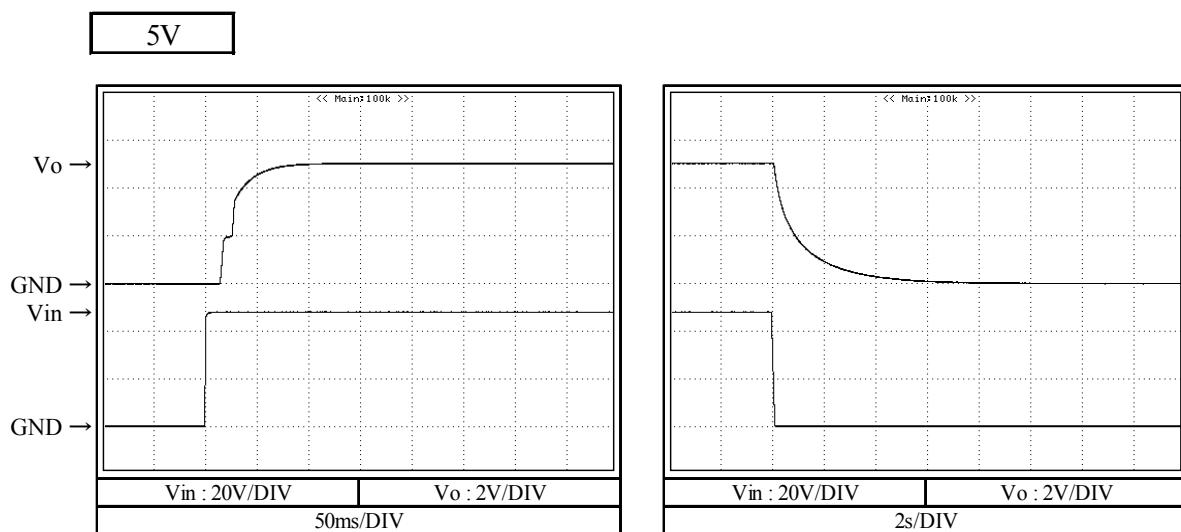
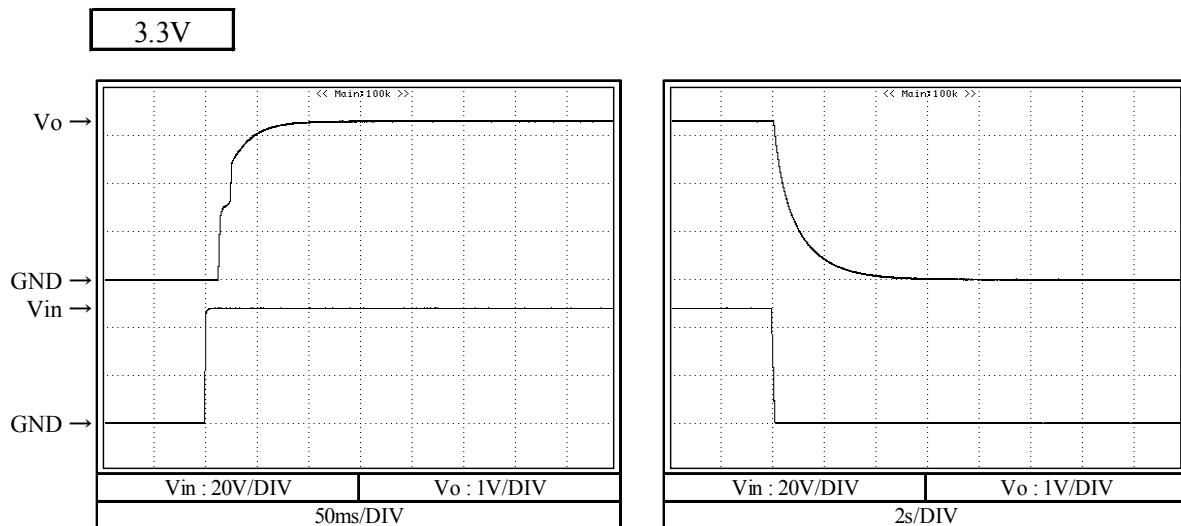


15V



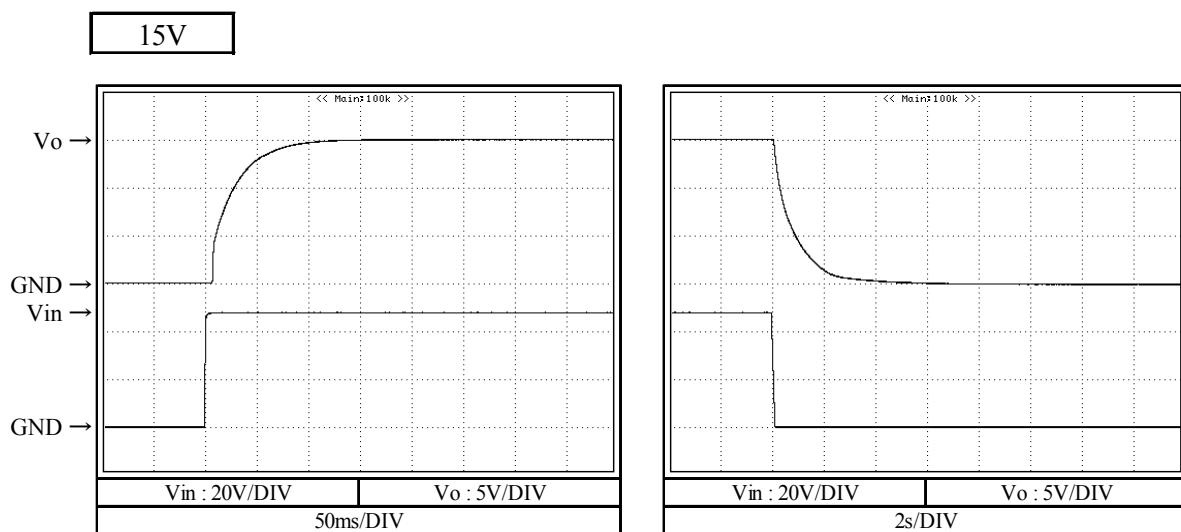
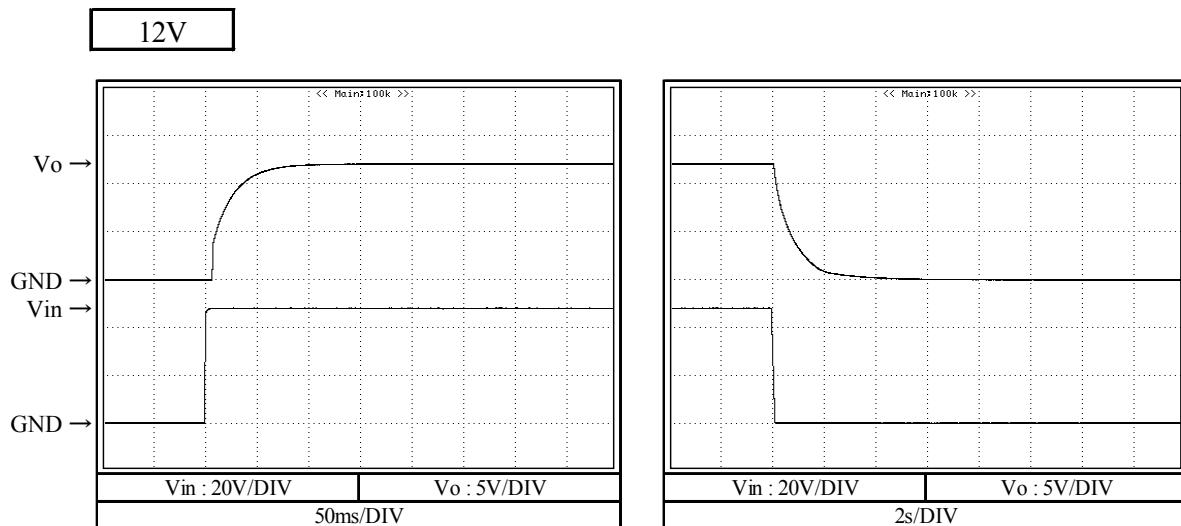
2-5. 出力立ち上がり・立ち下がり特性 Output rise and fall characteristics

Conditions Vin : 48 VDC
 Io : 0 %
 Ta : 25 °C



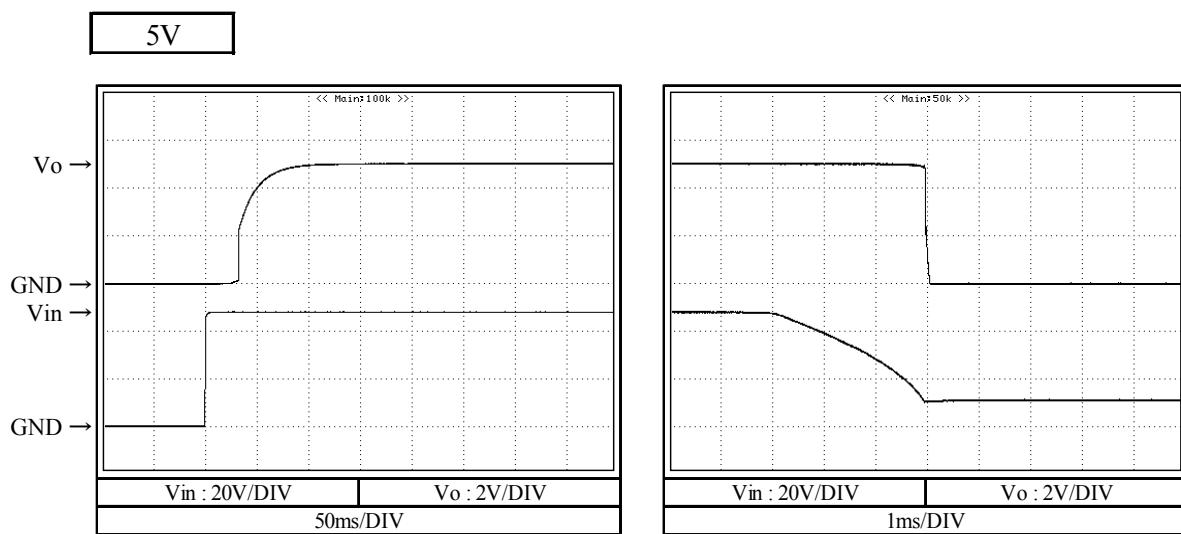
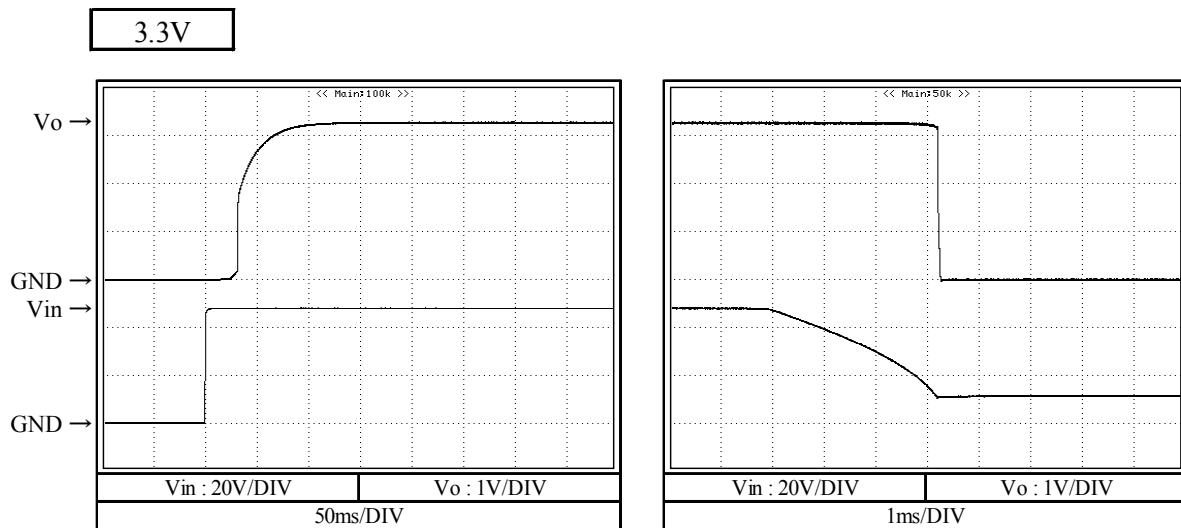
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Conditions Vin : 48 VDC
 Io : 0 %
 Ta : 25 °C



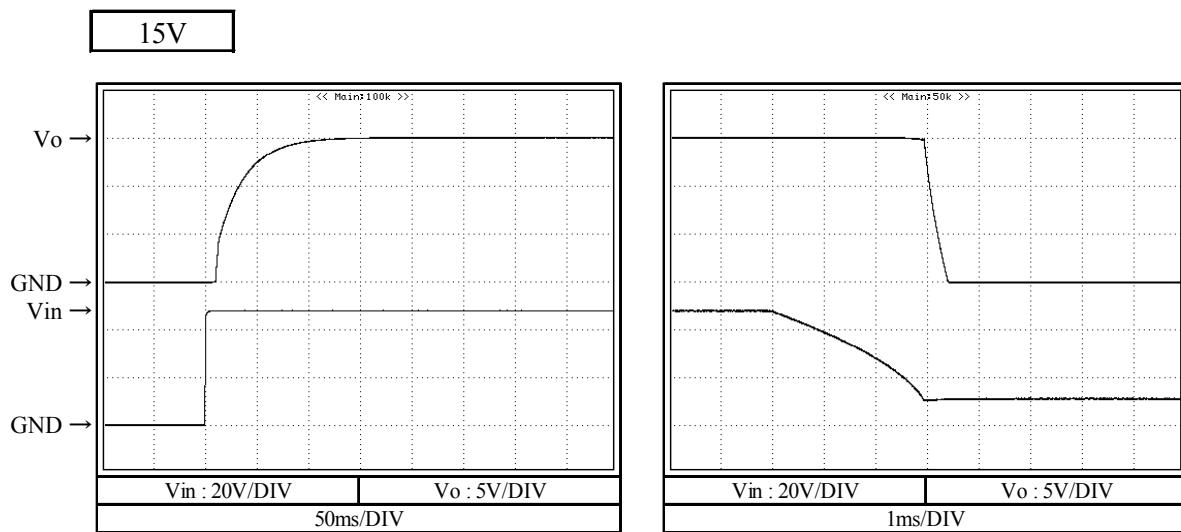
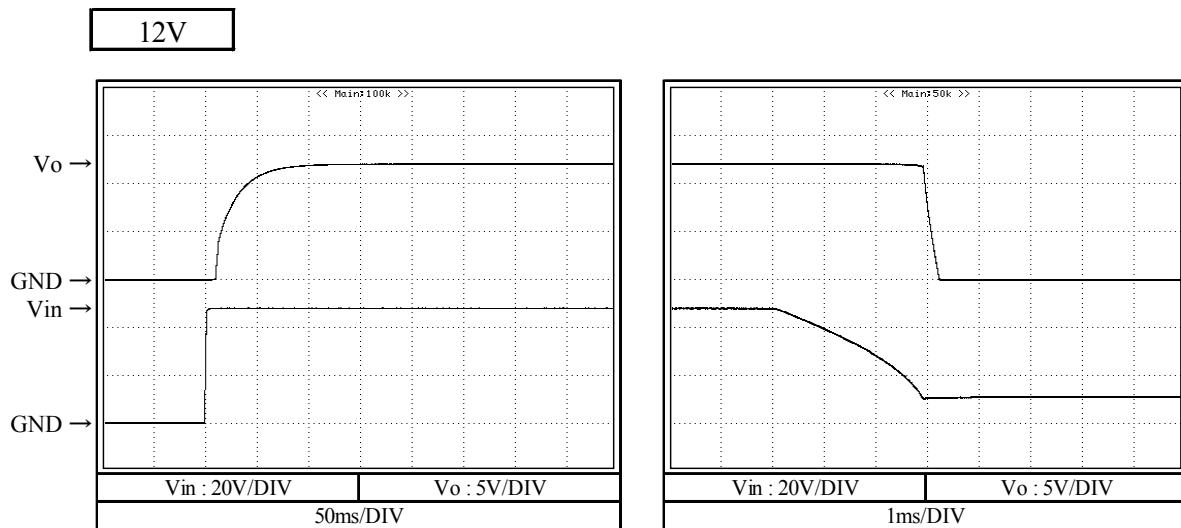
2-5. 出力立ち上がり・立ち下がり特性 Output rise and fall characteristics

Conditions Vin : 48 VDC
 Io : 100 %
 Ta : 25 °C



2-5. 出力立ち上がり・立ち下がり特性 Output rise and fall characteristics

Conditions Vin : 48 VDC
 Io : 100 %
 Ta : 25 °C

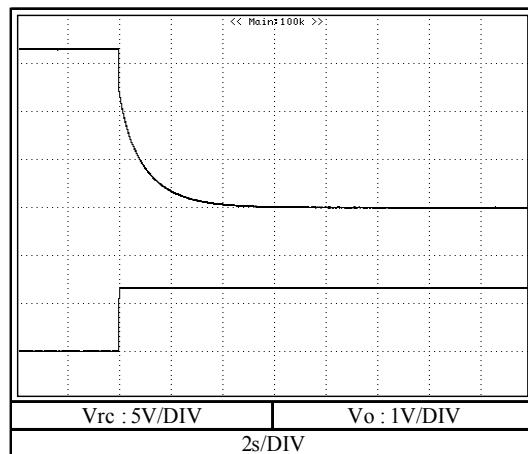
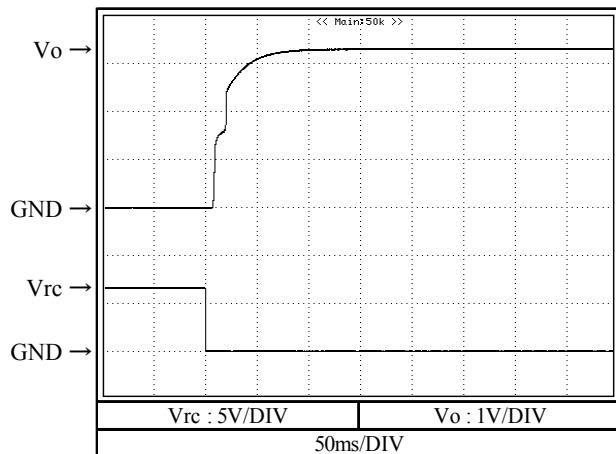


2-5. 出力立ち上がり・立ち下がり特性 (リモートON/OFFコントロール時)

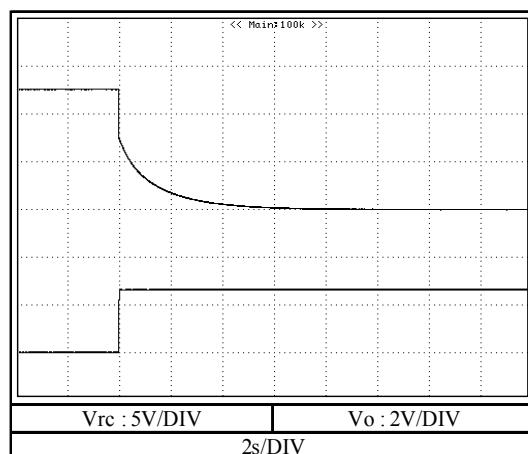
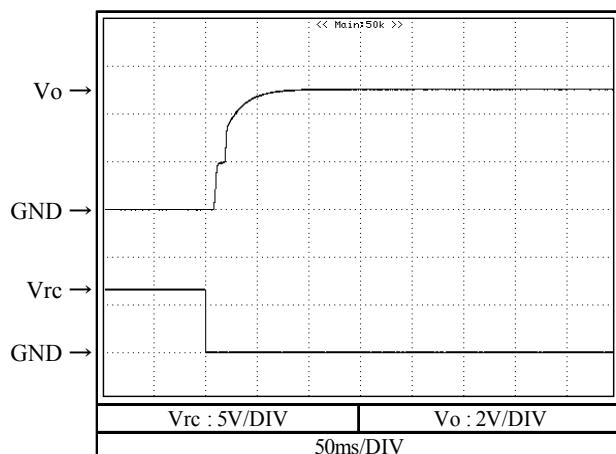
Output rise and fall characteristics with REMOTE ON/OFF CONTROL

Conditions Vin : 48 VDC
 Io : 0 %
 Ta : 25 °C

3.3V



5V

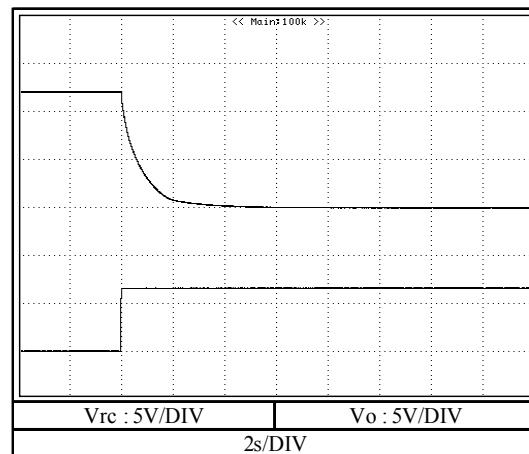
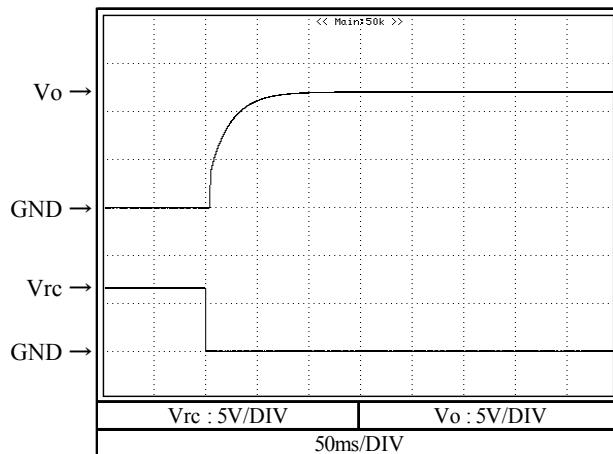


2-5. 出力立ち上がり・立ち下がり特性 (リモートON/OFFコントロール時)

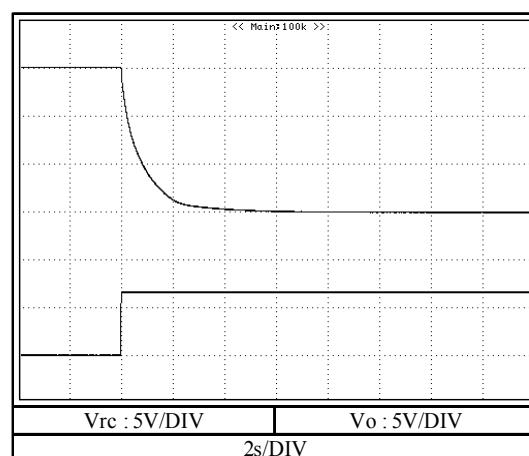
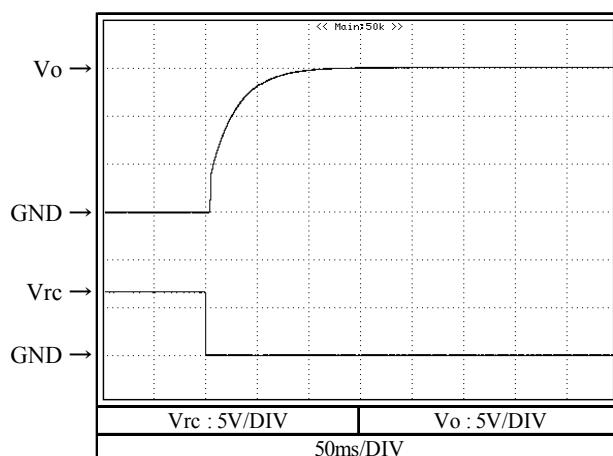
Output rise and fall characteristics with REMOTE ON/OFF CONTROL

Conditions Vin : 48 VDC
 Io : 0 %
 Ta : 25 °C

12V



15V

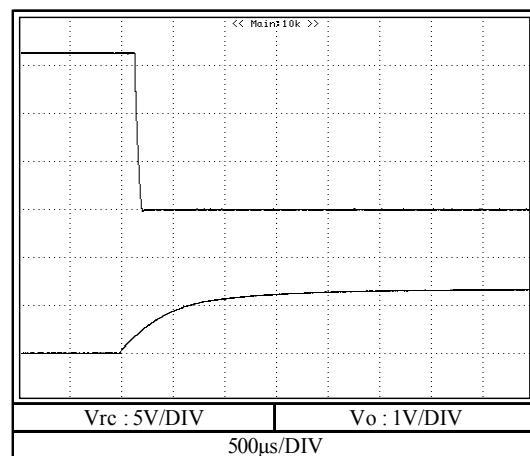
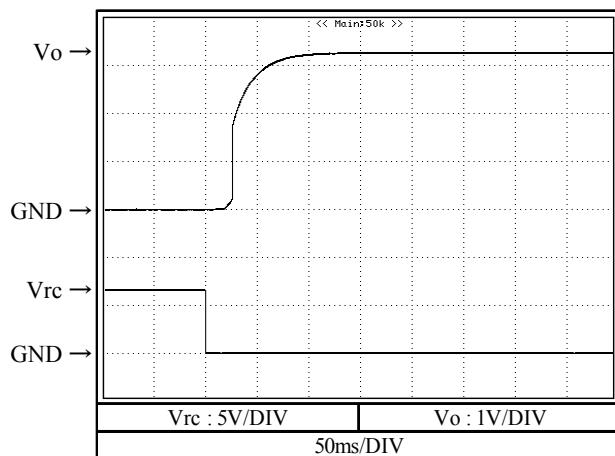


2-5. 出力立ち上がり・立ち下がり特性 (リモートON/OFFコントロール時)

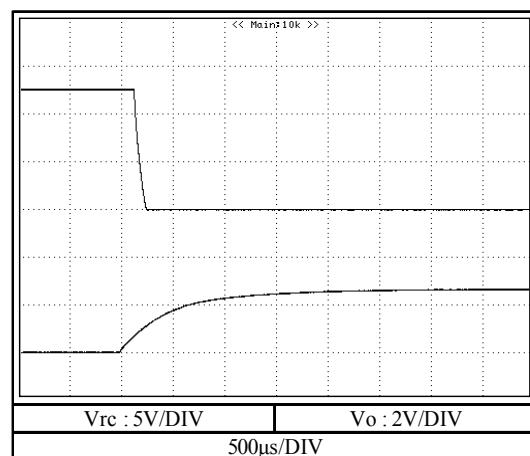
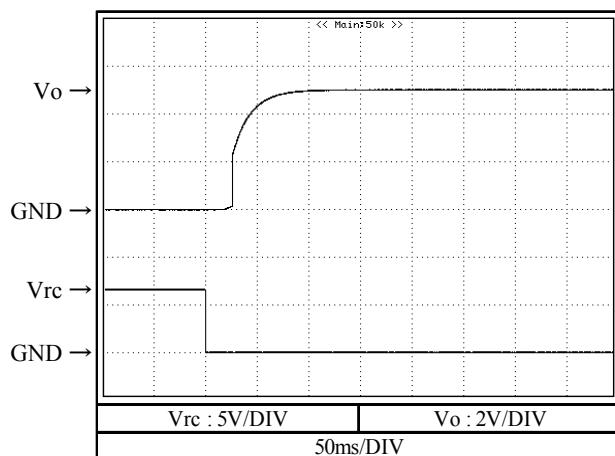
Output rise and fall characteristics with REMOTE ON/OFF CONTROL

Conditions Vin : 48 VDC
 Io : 100 %
 Ta : 25 °C

3.3V



5V

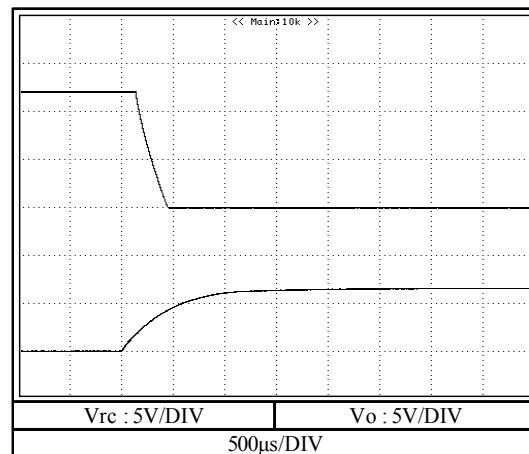
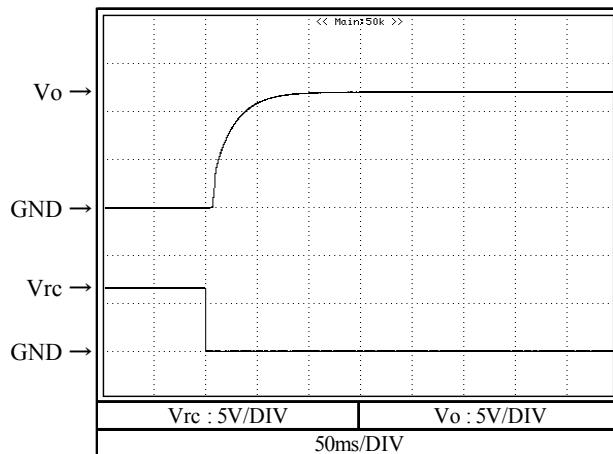


2-5. 出力立ち上がり・立ち下がり特性 (リモートON/OFFコントロール時)

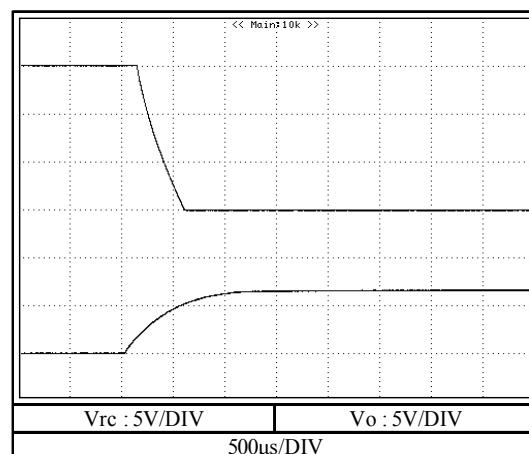
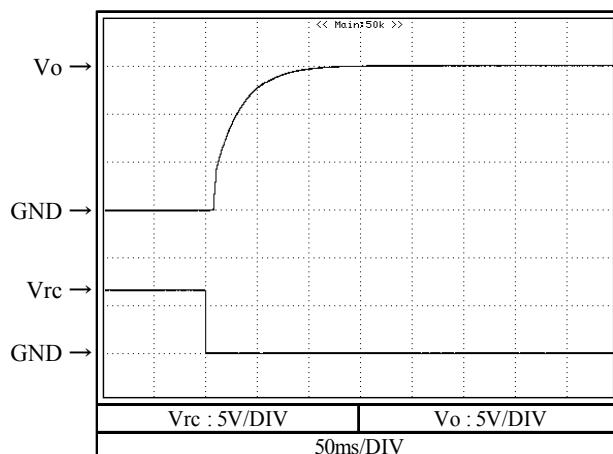
Output rise and fall characteristics with REMOTE ON/OFF CONTROL

Conditions Vin : 48 VDC
 Io : 100 %
 Ta : 25 °C

12V

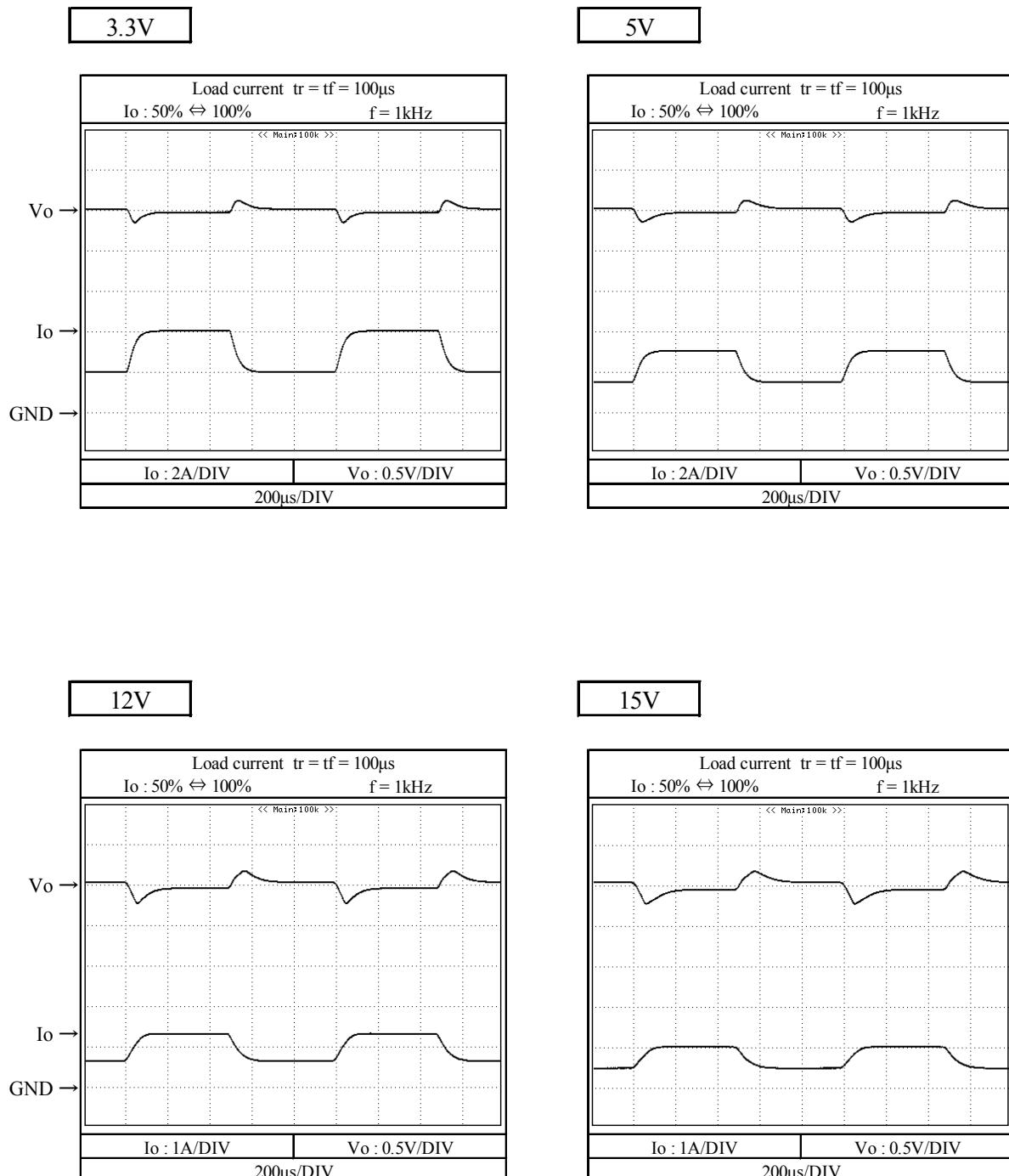


15V



2-6. 過渡応答(負荷急変)特性 Dynamic load response characteristics

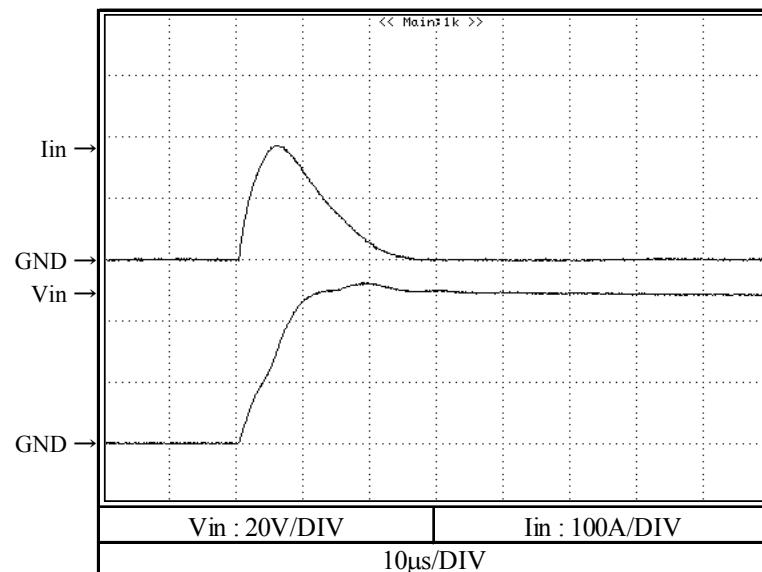
Conditions Vin : 48 VDC
 Io : 100 %
 Ta : 25 °C



2-7. 入力サージ電流(突入電流)特性 Inrush current characteristics

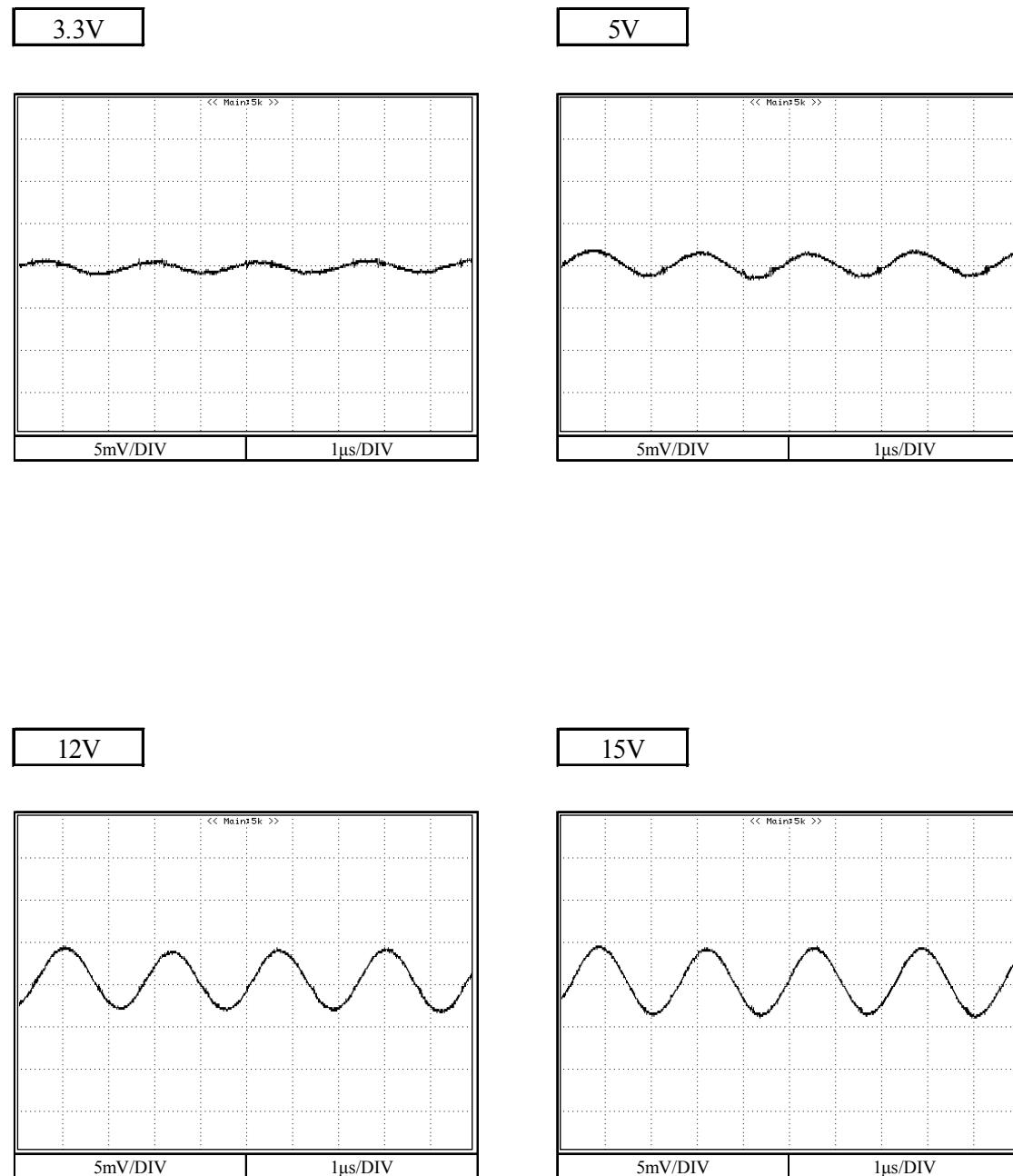
Conditions Vin : 48 VDC
Io : 100 %
Ta : 25 °C

5V



2-8. 出力リップル、ノイズ波形 Output ripple and noise waveform

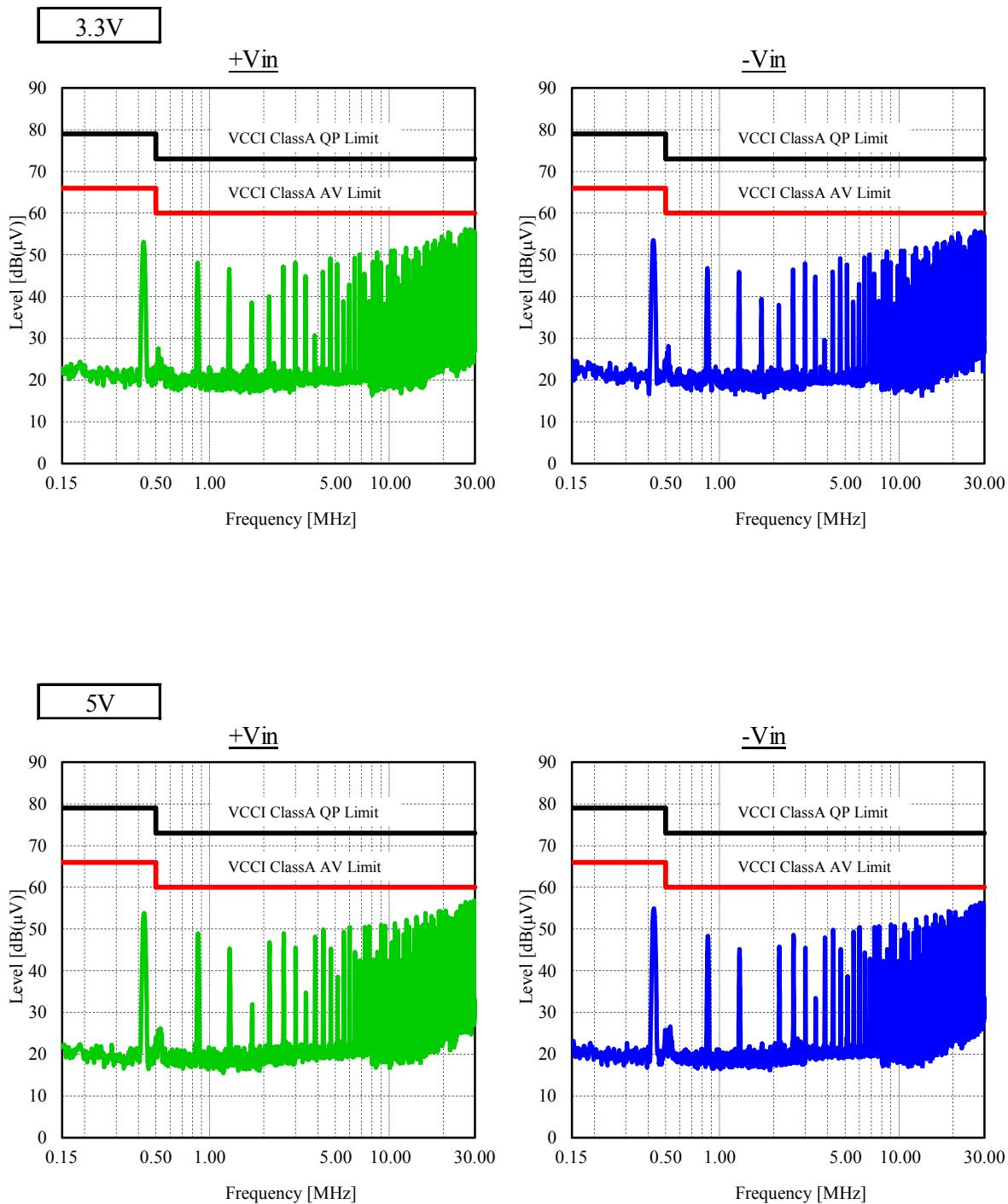
Conditions Vin : 48 VDC
Io : 100 %
Ta : 25 °C



2-9. EMI特性 Electro-Magnetic Interference characteristics

(a) 雜音端子電圧 (帰還ノイズ) Conducted Emission Noise

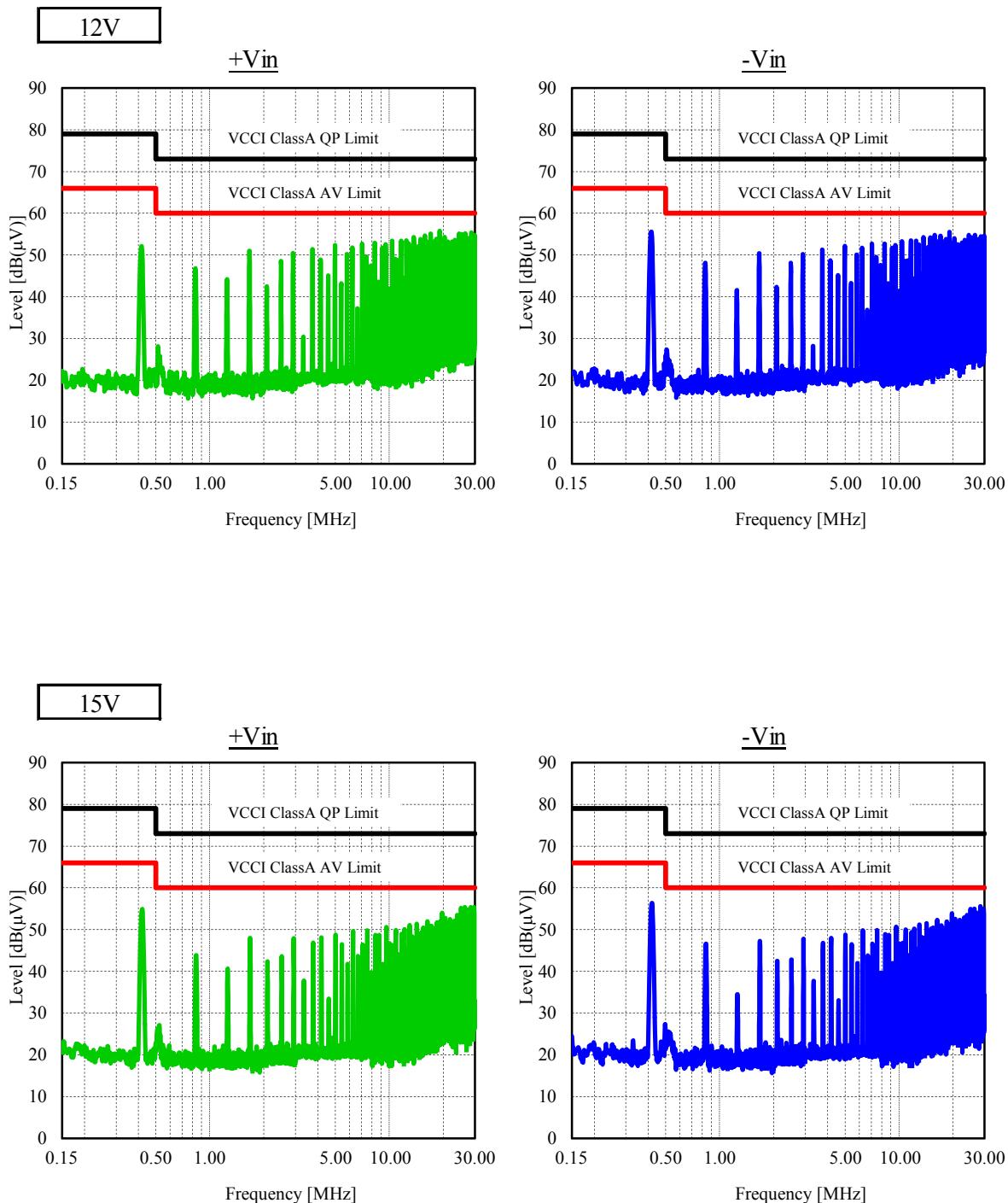
Conditions Vin : 48 VDC
 Io : 100 %
 Ta : 25 °C



2-9. EMI特性 Electro-Magnetic Interference characteristics

(a) 雜音端子電圧 (帰還ノイズ) Conducted Emission Noise

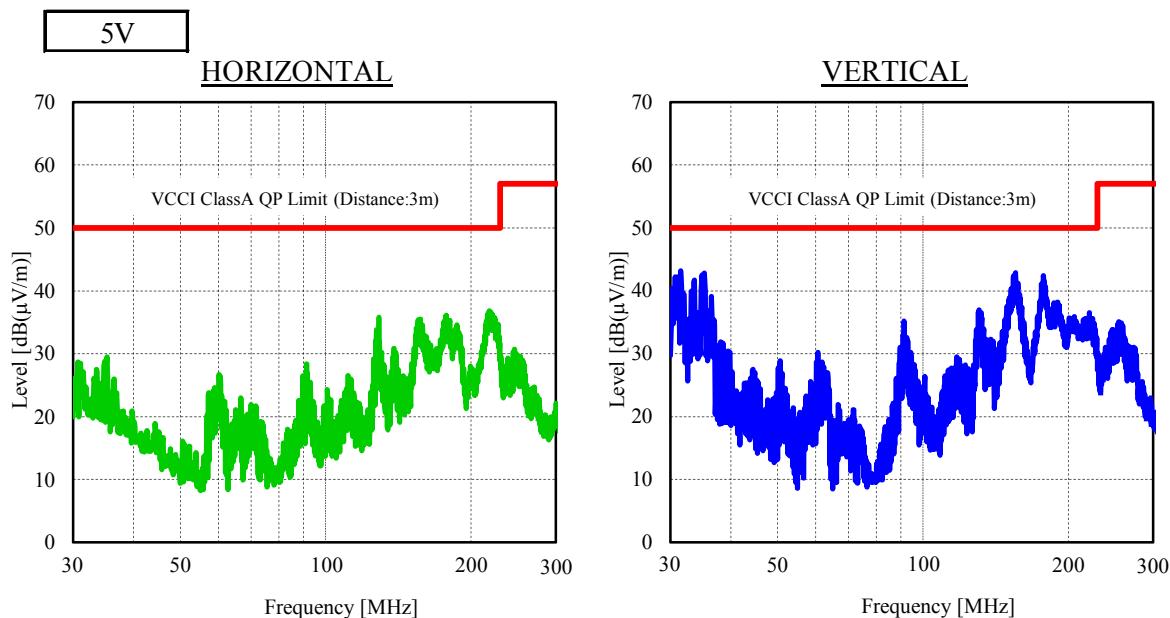
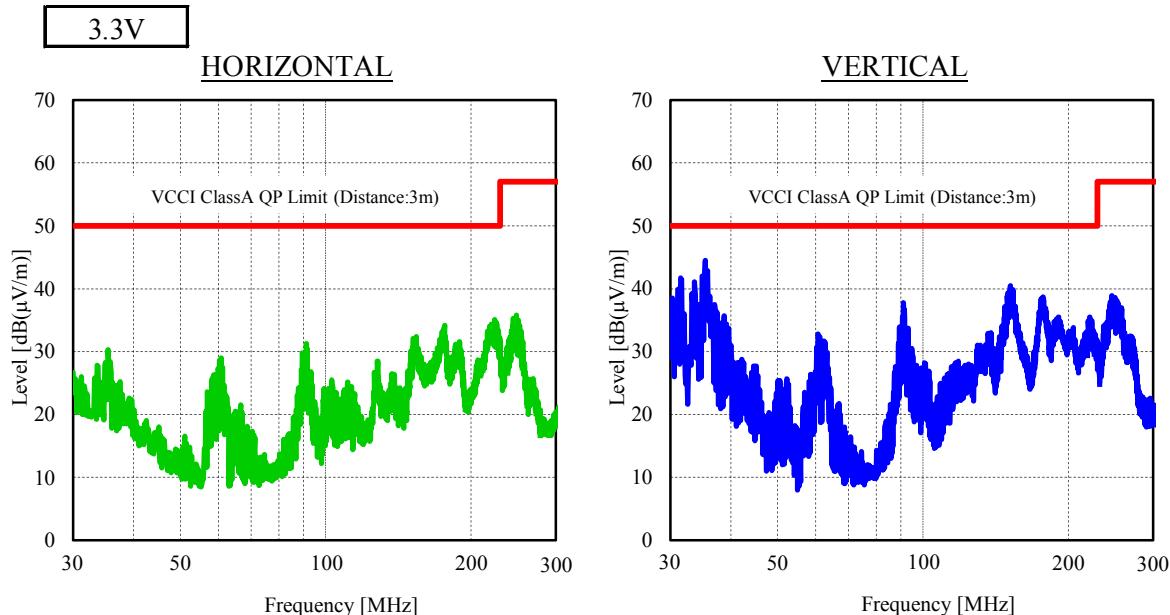
Conditions Vin : 48 VDC
 Io : 100 %
 Ta : 25 °C



2-9. EMI特性 Electro-Magnetic Interference characteristics

(b) 雜音電界強度 (輻射ノイズ) Radiated Emission Noise

Conditions Vin : 48 VDC
 Io : 100 %
 Ta : 25 °C



2-9. EMI特性 Electro-Magnetic Interference characteristics

(b) 雜音電界強度 (輻射ノイズ) Radiated Emission Noise

Conditions Vin : 48 VDC
 Io : 100 %
 Ta : 25 °C

